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HEARING AID COMPATIBILITY

Applicant Name:
Samsung Electronics Co., Ltd.
416 Maetan 3-Dong, Yeongtong-gu, Suwon-si
Gyeonggi-do, 443-742, Republic of Korea

Date of Testing:
Aug. 30 - Sept. 4, 2012
Test Site/Location:
PCTEST Lab, Columbia, MD, USA
Test Report Serial No.:
0Y1209101318.A3L

FCC ID:	**A3LSCHI605**
APPLICANT:	**SAMSUNG ELECTRONICS CO., LTD.**

Scope of Test:	RF Emissions Testing
Application Type:	Certification
FCC Rule Part(s):	§ 20.19(b)
HAC Standard:	ANSI C63.19-2007 §6.3(v), §7.3(v); CTIA Test Plan for Hearing Aid Compatibility Rev 2.0, April 2010
EUT Type:	Portable Handset
Model(s):	SCH-I605
Tx Frequencies Tested:	824.70 - 848.31 MHz (Cellular CDMA) 1851.25 - 1908.75 MHz (PCS CDMA) 824.20 - 848.80 MHz (GSM 850) 1850.20 - 1909.80 MHz (GSM 1900) 826.40 - 846.60 MHz (WCDMA850) 1852.4 - 1907.6 MHz (WCDMA1900)
Test Device Serial No.:	*Pre-Production Sample* [S/N: 332F0]

C63.19-2007 HAC Category:	**M3 (RF EMISSIONS CATEGORY)**

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2007 and had been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested and are for North American Bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

PCTEST certifies that no party to this application has been subject to a denial of Federal benefits that includes FCC benefits pursuant to Section 5301 of the Anti-Drug Abuse Act of 1988, 21 U.S.C. 862.

Randy Ortanez
President

CTIA Authorized Test Lab
LAB CODE 20020221-00

ACCREDITED
TESTING LABORATORY
CERTIFICATE #2041.01

TABLE OF CONTENTS

1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658[1] to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- RF Magnetic-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.

Figure 1-1 Hearing Aid *in-vitu*

[1] FCC Rule & Order, WT Docket 01-309 RM-8658

2. TEST SITE LOCATION

2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2).

Figure 2-1
Map of the Greater Baltimore and Metropolitan Washington, D.C. area

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in New Concept Business Park, Guilford Industrial Park, Columbia, Maryland. The site address is 6660-B Dobbin Road, Columbia, MD 21045. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 11'15" N latitude and 76° 49' 38" W longitude. The facility is 1.5 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory. There are no FM or TV transmitters within 15 miles of the site. The detailed description of the measurement facility was found to be in compliance with the requirements of § 2.948 according to ANSI C63.4 on January 27, 2006 and Industry Canada.

2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD 21045, U.S.A.

- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing, Hearing-Aid Compatibility (HAC), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).
- PCTEST TCB is a Telecommunication Certification Body (TCB) accredited to ISO/IEC Guide 65 by the American National Standards Institute (ANSI) in all scopes of FCC Rules and all Industry Canada Standards (RSS).
- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for AMPS and CDMA, and EvDO mobile phones.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for Over-the-Air (OTA) Antenna Performance testing for AMPS, CDMA, GSM, GPRS, EGPRS, UMTS (W-CDMA), CDMA 1xEVDO Data, CDMA 1xRTT Data.

3. EUT DESCRIPTION

FCC ID:	A3LSCHI605
Manufacturer:	Samsung Electronics Co., Ltd. 416 Maetan 3-Dong, Yeongtong-gu, Suwon-si Gyeonggi-do, 443-742, Republic of Korea
Model(s):	SCH-I605
Serial Number:	332F0
Tx Frequencies Tested:	824.70 - 848.31 MHz (Cellular CDMA) 1851.25 - 1908.75 MHz (PCS CDMA) 824.20 - 848.80 MHz (GSM 850) 1850.20 - 1909.80 MHz (GSM 1900) 826.40 - 846.60 MHz (WCDMA850) 1852.4 - 1907.6 MHz (WCDMA1900)
Antenna Configurations:	Internal Antenna
Maximum Tested Conducted Power (HAC):	24.94 dBm (Cell. CDMA), 24.58 dBm (PCS CDMA), 32.77 dBm (GSM 850), 29.65 dBm (GSM 1900), 22.45 dBm (WCDMA850), 22.49 dBm (WCDMA1900)
HAC Test Configurations:	Cell. CDMA, 1013, 384, 777, BT Off, WLAN Off, LTE Off PCS CDMA, 25, 600, 1175, BT Off, WLAN Off, LTE Off GSM 850, 128, 190, 251, BT Off, WLAN Off, LTE Off GSM 1900, 512, 661, 810, BT Off, WLAN Off, LTE Off WCDMA850, 4132, 4183, 4233, BT Off, WLAN Off, LTE Off WCDMA1900, 9262, 9400, 9538, BT Off, WLAN Off, LTE Off
EUT Type:	Portable Handset

Air-Interface	Band (MHz)	Type	C63.19/tested	Simultaneous Transmissions (Not to be tested)	Reduced power 20.19 (c)(1)	Voice Over Digital Transport (Data)
GSM	850	Voice	Yes	Yes: BT or WIFI	N/A	N/A
	1900					
	GPRS/EDGE	Data	N/A	Yes: BT or WIFI	N/A	Yes
WCDMA	850	Voice	Yes	Yes: BT or WIFI	N/A	N/A
	1900					
	HSPA	Data	N/A	Yes: BT or WIFI	N/A	Yes
CDMA	850	Voice	Yes	Yes: LTE, BT or WIFI	N/A	N/A
	1900				N/A	N/A
	EVDO	Data	N/A	Yes: LTE, BT or WIFI	N/A	Yes
LTE (B13)	780	Data	N/A	Yes: CDMA, BT or WIFI	N/A	Yes
BT	2450	Data	N/A	Yes: GSM, WCDMA, CDMA or LTE	N/A	N/A
WIFI	2450	Data	N/A	Yes: GSM, WCDMA, CDMA or LTE	N/A	Yes
	5200					
	5300					
	5500					
	5800					
NOTE: HAC Rating was not based on concurrent voice and data modes. Standalone mode was found to represent worst case rating.						

Table 3: A3LSCHI605 Air Interfaces

4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters	
Near field Category	**E-field emissions CW dB(V/m)**	**H-field emissions CW dB(A/m)**
f < 960 MHz		
M1	56 to 61 + 0.5 x AWF	5.6 to 10.6 +0.5 x AWF
M2	51 to 56 + 0.5 x AWF	0.6 to 5.6 +0.5 x AWF
M3	46 to 51 + 0.5 x AWF	–4.4 to 0.6 +0.5 x AWF
M4	< 46 + 0.5 x AWF	< –4.4 + 0.5 x AWF
f > 960 MHz		
M1	46 to 51 + 0.5 x AWF	–4.4 to 0.6 +0.5 x AWF
M2	41 to 46 + 0.5 x AWF	–9.4 to –4.4 +0.5 x AWF
M3	36 to 41 + 0.5 x AWF	–14.4 to –9.4 +0.5 x AWF
M4	< 36 + 0.5 x AWF	< –14.4 + 0.5 x AWF

Table 4-1
Hearing aid and WD near-field categories as defined in ANSI C63.19-2007

II. ARTICULATION WEIGHTING FACTOR (AWF)

Standard	Technology	Articulation Weighing Factor (AWF)
T1/T1P1/3GPP	**UMTS (WCDMA)**	0
TIA/EIA/IS-2000	**CDMA**	0
iDEN^{T}	**TDMA (22 and 11 Hz)**	0
J-STD-007	**GSM (217 Hz)**	-5

Table 4-2
Articulation Weighting Factors

5. SYSTEM SPECIFICATIONS

ER3DV6 E-Field Probe Description

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%, k=2)
Frequency:	100 MHz to > 6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m (M3 or better device readings fall well below diode compression point)
Linearity:	± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm

Figure 5-1
E-field Free-space Probe

H3DV6 H-Field Probe Description

Construction:	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges
Frequency:	200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2); Output linearized
Directivity:	± 0.25 dB (spherical isotropy error)
Dynamic Range:	10 mA/m to 2 A/m at 1 GHz (M3 or better device readings fall well below diode compression point)
Dimensions:	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm
E-Field Interference:	< 10% at 3 GHz (for plane wave)

Figure 5-2
H-Field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

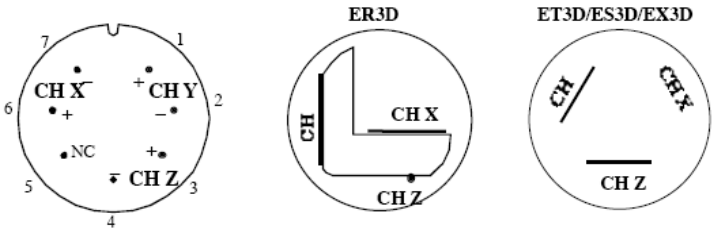
Magnetic field sensors are measuring the integral of the H-field across their sensor area surrounded by the loop. They are calibrated in a precise, homogeneous field. When measuring a gradient field, the result will be very close to the field in the center of the loop which is equivalent to the value of a homogeneous field equivalent to the center value. But it will be different from the field at the border of the loop.

Consequently, two sensors with different loop diameters - both calibrated ideally - would give different results when measuring from the edge of the probe sensor elements. The behavior for electrically small E-field sensors is equivalent.

The magnetic field loops of the H3D probes are concentric, with the center 3mm from the tip for H3DV6. Their radius is 1.9mm.

The electric field probes have a more irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.

Connector Plan



(seen from back) (seen from front)

The antistatic shielding inside the probe is connected to the probe connector case.

Instrumentation Chain

Equation 1

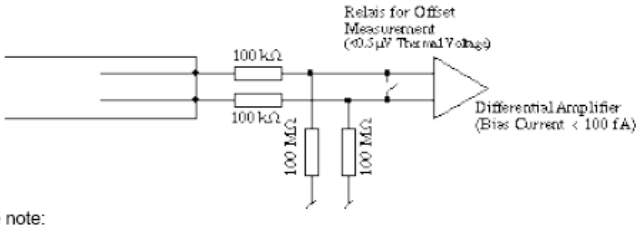
Conversion of Connector Voltage u_i to E-Field E_i

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

E_i:	electric field in V/m
u_i:	voltage of channel i at the connector in μV
$Norm_i$:	sensitivity of channel i in μV/(V/m)^2
$ConvF$:	enhancement factor in liquid (ConvF=1 for Air)
DCP:	diode compression point in μV
CF:	signal crest factor (peak power/average power)

Conditions of Calibration



Please note:
- a lower input impedance of the amplifier will result in different sensitivity factors $Norm_i$ and DCP
- larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

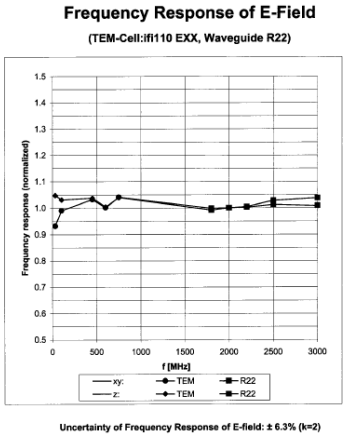


Figure 5-3 E-Field Probe Frequency Response

H-field sensors have a frequency dependent sensitivity which is evaluated for a series of frequencies also visible in the probe calibration certificate. The calibration factors result from a fitting algorithm. The proper conversion is calculated by the DASY4 software depending on the frequency setting in the procedure. See below for H-field frequency response:

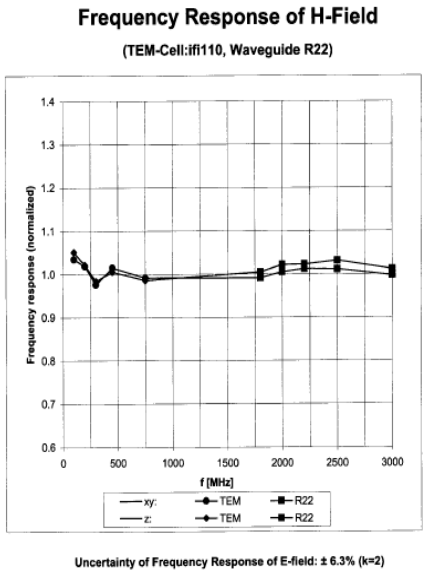


Figure 5-4 H-Field Probe Frequency Response

Conversion to Peak

Peak is defined as Peak Envelope Power. All raw measurements from the HAC measurement system are RMS values. The DASY4 system incorporates the crest factor of the signal in the computation of the RMS values (See Equation 1). Although the software also has capability to estimate the peak field by applying a square root of crest factor value to the readings, the probe modulation factor was applied manually instead per C63.19 in the measurement tables in this report. The equation to convert the raw measurements in the data tables are:

$$\text{Peak Field} = 20 \cdot \log (\text{Raw} \cdot \text{PMF})$$

Where:

Peak Field = Peak field (in dBV/m or dBA/m)
Raw = Raw field measurement from the measurement system (in V/m or A/m).
PMF = Probe Modulation Factor (in linear units).

SPEAG Robotic System

E-field and H-field measurements are performed using the DASY4 automated dosimetric assessment system. The DASY4 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Pentium 4 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).

Figure 5-5
SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the Gateway Pentium 4 2.53 GHz computer with Windows XP system and RF Measurement Software DASY4 v4.5 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

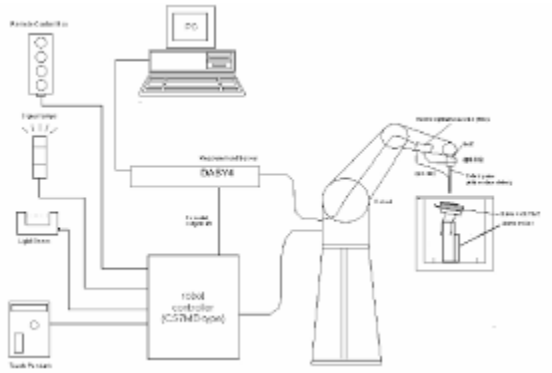


Figure 5-6
SPEAG Robotic System Diagram

DASY4 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_i = U_i + U_i^2 \cdot \frac{cf}{dcp_i}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	U_i	= input signal of channel i	(i = x, y, z)
	cf	= crest factor of exciting field	(DASY parameter)
	dcp_i	= diode compression point	(DASY parameter)

From the compensated input signals the primary field data for each channel can be evaluated:

$$\text{E} - \text{fieldprobes}: \qquad E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

$$\text{H} - \text{fieldprobes}: \qquad H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1} f + a_{i2} f^2}{f}$$

with	V_i	= compensated signal of channel i	(i = x, y, z)
	$Norm_i$	= sensor sensitivity of channel i $\mu V/(V/m)^2$ for E-field Probes	(i = x, y, z)
	$ConvF$	= sensitivity enhancement in solution	
	a_{ij}	= sensor sensitivity factors for H-field probes	
	f	= carrier frequency [GHz]	
	E_i	= electric field strength of channel i in V/m	
	H_i	= magnetic field strength of channel i in A/m	

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500 ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500 ms and a probe response time of <5 ms. In the current implementation, DASY4 waits longer than 100 ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

6. TEST PROCEDURE

I. RF EMISSIONS

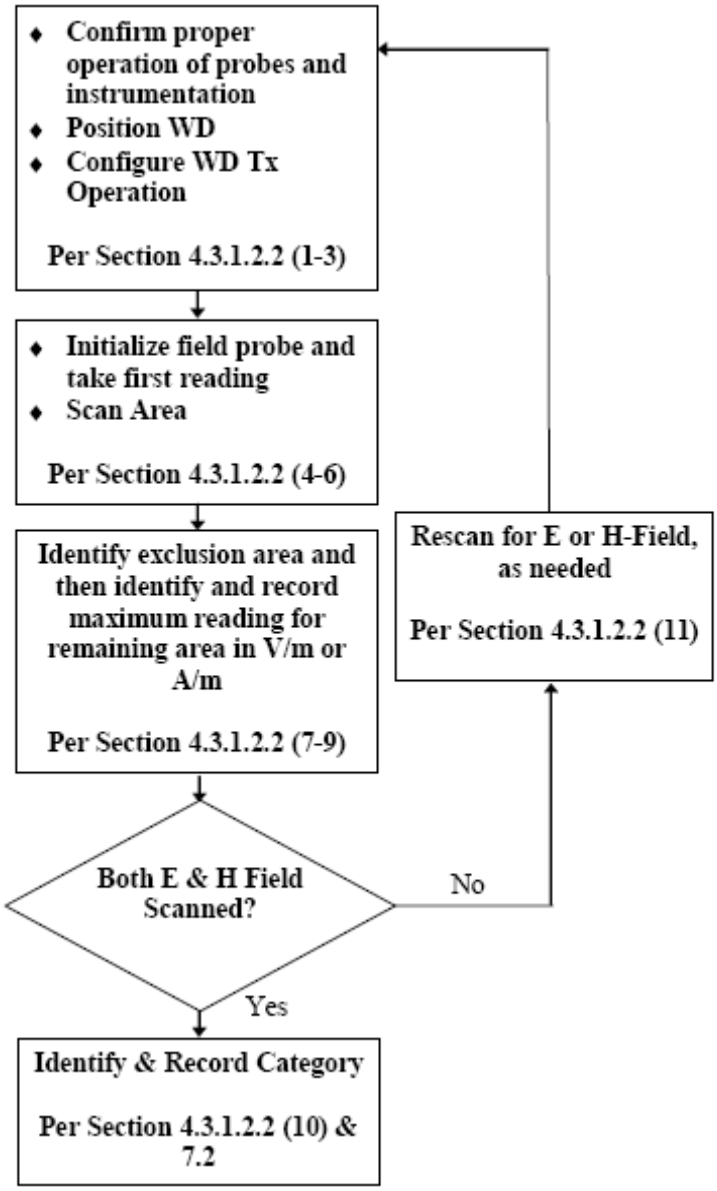


Figure 6-1
WD Near-Field Emissions Flow Chart

Test Setup

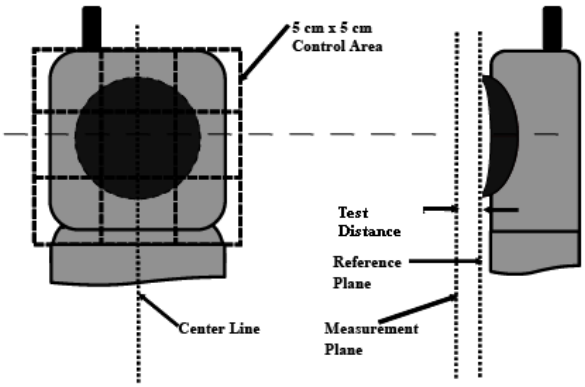


Figure 6-2
E/H-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

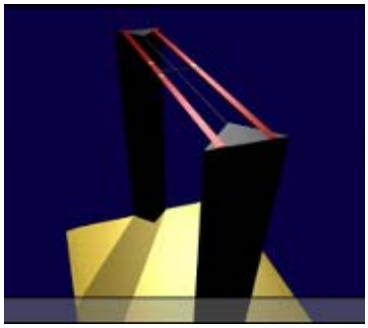


Figure 6-3
HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.

2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.

3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.

4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.

5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.

6. The measurement system measured the field strength at the reference location.

7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360^{o} rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.

8. The system performed a drift evaluation by measuring the field at the reference location.

9. Steps 1-8 were done for both the E and H-Field measurements.

7. SYSTEM CHECK

I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1 cm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:

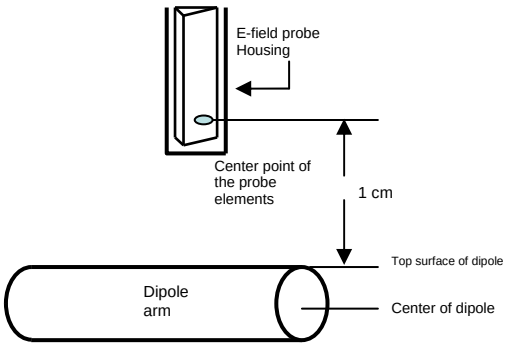


Figure 7-1
Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device (e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (i.e. - 20dBm) RMS after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.

Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (

see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

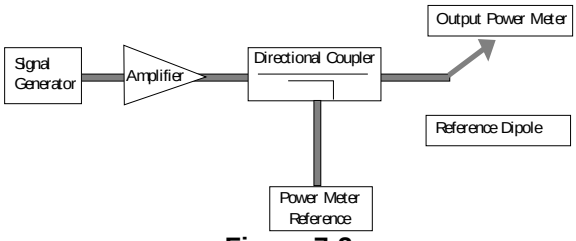


Figure 7-2
Setup for Desired Output Power to Dipole

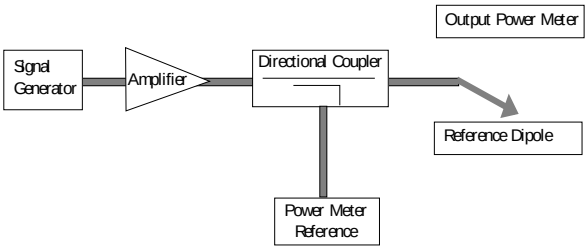


Figure 7-3
Setup to Dipole

Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:

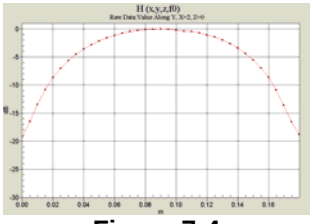


Figure 7-4
2-D Raw Data from scan along dipole axis

Figure 7-5
2-D Interpolated points from scan along dipole axis

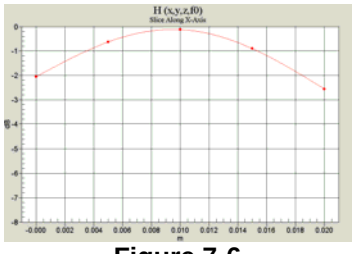


Figure 7-6
2-D Raw Data from scan along transverse axis

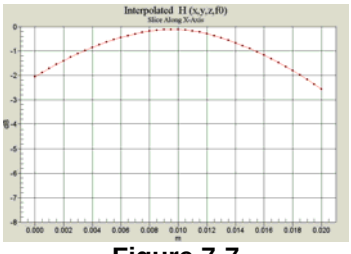


Figure 7-7
2-D Interpolated points from scan along transverse axis

III. System Check Results

Validation Results

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	164.1	**166.0**	**-1.1%**
1880	1137	20.0	132.9	**136.8**	**-2.9%**

Frequency (MHz)	Dipole S/N	Input Power (dBm)	H-field Result (A/m)	Target Field (A/m)	% Deviation
835	1003	20.0	0.470	**0.458**	**2.6%**
1880	1137	20.0	0.446	**0.460**	**-3.1%**

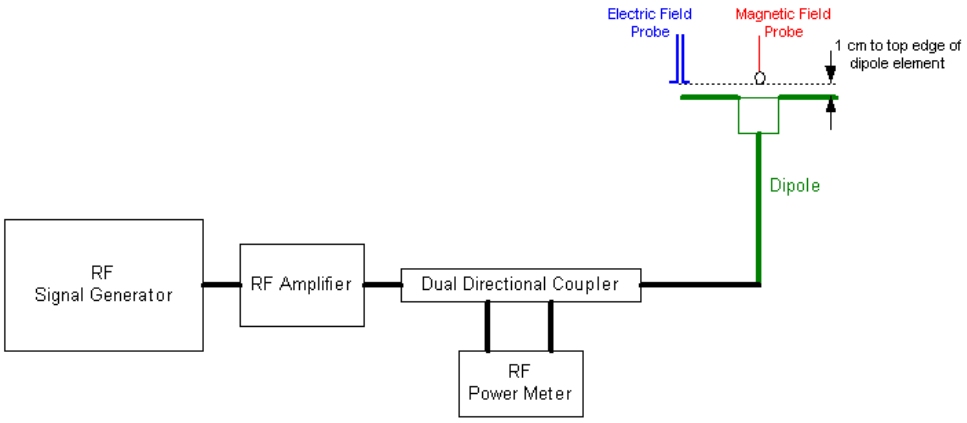


Figure 7-8
System Check Setup

8. MODULATION FACTOR

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

All voice modes for this device have been investigated in this section of the report. According to the FCC 3G Measurement Procedures, May 2006 for RF Emissions, variations in peak field and power readings.

This was done using the following procedure:

1. The probe was illuminated with a CW signal at the intended measurement frequency and wireless device power.
2. The probe was positioned at the field maxima over the dipole antenna (determined after an area scan over the dipole) illuminated with the CW signal.
3. The reading of the probe measurement system of the CW signal at the maximum point was recorded.
4. Using a Spectrum Analyzer, the modulated signal adjusted with the same peak level of the CW signal was determined.
5. The probe measurement system reading was recorded with the modulated signal. The appropriate system crest factors for the modulation type were configured in the software to the system measurements.
6. The ratio of the CW reading to modulated signal reading is the probe modulation factor (PMF) for the modulation and field probe combination. This was repeated for 80% AM.
7. Steps 1-6 were repeated at all frequency bands and for both E and H field probes.

The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

$$\text{Peak} = 20 \cdot \log (\text{Raw} \cdot \text{PMF})$$

This method correlates well with the modulation using the DUT in the alternative substitution method. See below for correlation of signal:

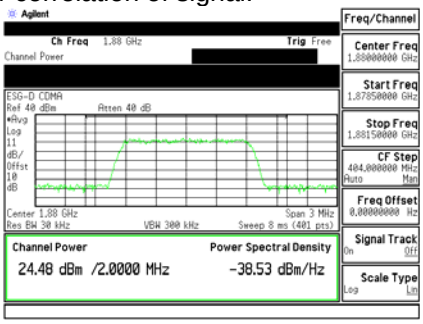


Figure 8-1
Signal Generator Modulated Signal

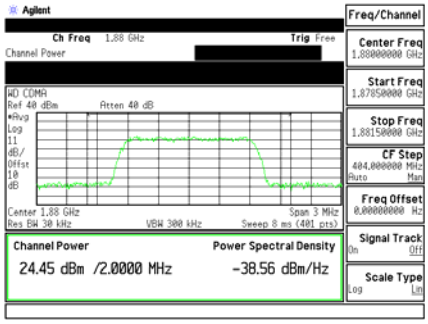


Figure 8-2
Wireless Device Modulated Signal

I. CDMA Modulation Factors

f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
835	AM	204.50	0.5971	1.411	1.326
835	CDMA	311.00	0.9799	0.928	0.808
835	CW	288.60	0.7915		
1880	AM	155.40	0.6561	1.445	1.501
1880	CDMA	226.80	1.2010	0.990	0.820
1880	CW	224.50	0.9846		
835	CDMA / SO3	46.28	0.2267	3.025	2.895
835	CW	140.00	0.6562		
1880	CDMA / SO3	58.27	0.1999	3.151	2.853
1880	CW	183.60	0.5704		

Table 8-1
CDMA Modulation Factors

FCC 3G Note: "CDMA" represents RC1/SO55 mode, while "CDMA/SO3" represents RC1/SO3 mode. Other modes were investigated and were within 0.25 dB of the RC1/SO55 configuration per Table 8-1.

CW and Modulated Signal Zero-Span plots:

Figure 8-3 Zero-Span Plots

II. GSM/WCDMA Modulation Factors

f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor	f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor
835	AM	629.3	2.212	1.290	0.910	835	AM	175.1	0.4947	1.385	1.313
835	GSM	287	1.033	2.829	1.948	835	WCDMA	252.3	0.703	0.961	0.924
835	CW	811.8	2.012			835	CW	242.5	0.6497		
1880	AM	390.8	1.215	1.319	1.115	1880	AM	129.2	0.5285	1.449	1.219
1880	GSM	184.8	0.5843	2.790	2.319	1880	WCDMA	192.5	0.6853	0.972	0.940
1880	CW	515.6	1.355			1880	CW	187.2	0.6442		

Table 8-2
GSM/WCDMA Modulation Factors

Spectrum Analyzer Plots of ESG-D Signal used for PMF measurements:

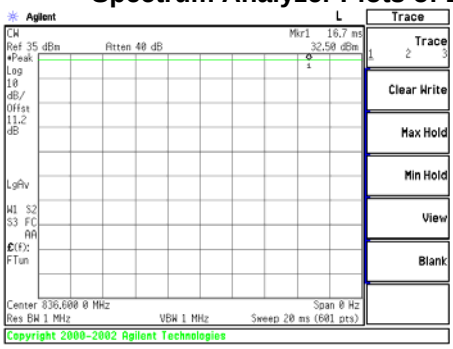


Figure 8-4 GSM850 CW Signal

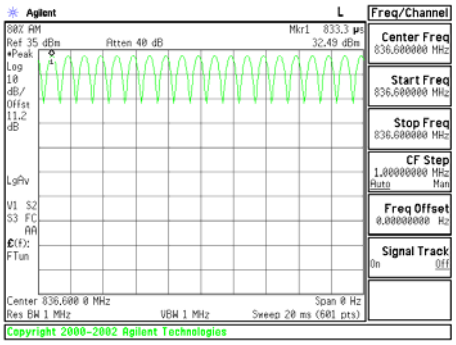


Figure 8-5 GSM850 80% AM Signal

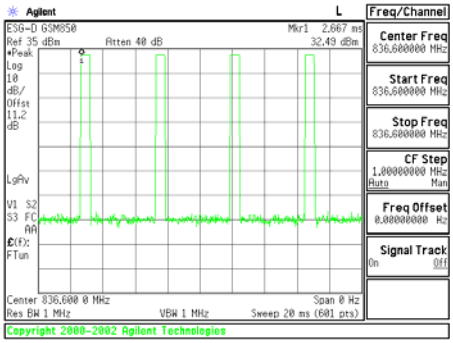


Figure 8-6 GSM850 Signal

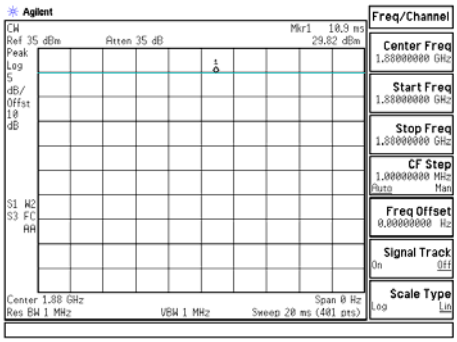


Figure 8-7 PCS CW Signal

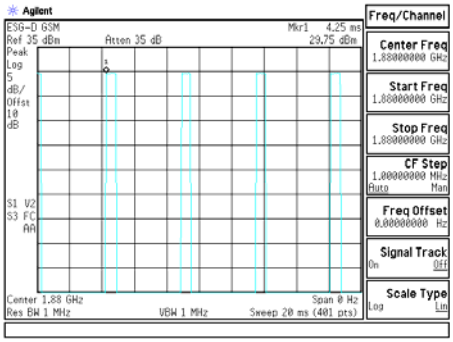


Figure 8-8 PCS GSM Signal

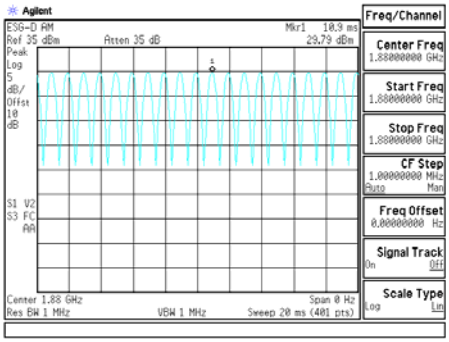


Figure 8-9 PCS 80% AM Signal

9. FCC 3G MEASUREMENTS

Power measurements were performed using a base station simulator under digital average power.

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator. The HAC measurement software calculates a reference point at the start and end of the test to check for power drifts. If power deviations of more than 5% occurred, the tests were repeated.

II. Conducted RF Output Power Measurements:

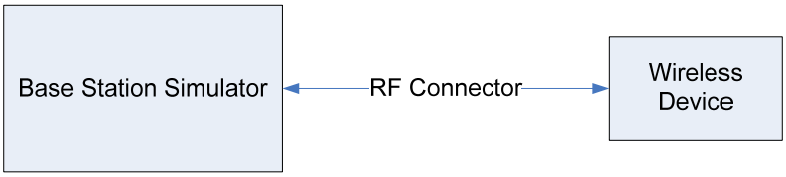


Figure 9-1
Power Measurement Setup

Band	Channel	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]
	F-RC	MHz	RC1	RC3	RC4	RC1	RC3	RC2	RC5	RC1	RC3	RC4
Cellular	1013	824.7	24.82	24.79	24.92	24.94	24.77	24.81	24.80	24.88	24.88	24.82
	384	836.52	24.71	24.68	24.82	24.82	24.82	24.67	24.66	24.77	24.73	24.74
	777	848.31	24.68	24.62	24.76	24.76	24.70	24.64	24.75	24.76	24.76	24.68
PCS	25	1851.25	24.29	24.26	24.40	24.38	24.40	24.41	24.38	24.16	24.29	24.27
	600	1880	24.49	24.36	24.46	24.36	24.44	24.51	24.47	24.42	24.35	24.43
	1175	1908.75	24.41	24.37	24.34	24.41	24.32	24.42	24.33	24.58	24.31	24.33

Table 9-1
CDMA Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)
Cellular	128	32.77
	190	32.67
	251	32.36
PCS	512	29.40
	661	29.65
	810	29.55

Table 9-2
GSM Conducted Powers

3GPP 34.121 Subtest	Cellular Band [dBm]			PCS Band [dBm]		
	4132	4183	4233	9262	9400	9538
12.2 kbps RMC	22.45	22.29	22.40	22.48	22.35	22.49
12.2 kbps AMR	22.62	22.51	22.61	22.50	22.42	22.47

Table 9-3
WCDMA Conducted Powers

III. CDMA Worst-Case RC/SO Investigation

Sample pre-testing of the various CDMA modes was performed at the worst case probe location as part of subset testing justification. Below are RC/SO mode investigation results of the device at the worst-case (maximum) field point location. The worst-case RC/SO was used for HAC testing.

Mode	Channel	Backlight	RC/SO	Scan Center	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
PCS	25	on	SO3/RC1	Acoustic	12.52	39.4	31.9	41.0	-9.08	M4	none
PCS	25	off	SO3/RC3	Acoustic	35.54	35.2	30.9	41.0	-10.07	M4	none
PCS	25	off	SO3/RC4	Acoustic	36.81	36.4	31.2	41.0	-9.77	M4	none
PCS	25	off	SO55/RC3	Acoustic	33.96	33.6	30.5	41.0	-10.47	M4	none
PCS	25	off	SO55/RC1	Acoustic	34.15	33.8	30.6	41.0	-10.42	M4	none
PCS	25	off	SO2/RC1	Acoustic	34.39	34.0	30.6	41.0	-10.36	M4	none
PCS	25	off	SO2/RC3	Acoustic	34.31	34.0	30.6	41.0	-10.38	M4	none
PCS	25	off	SO9/RC2	Acoustic	34.71	34.4	30.7	41.0	-10.28	M4	none
PCS	25	off	SO9/RC5	Acoustic	34.28	33.9	30.6	41.0	-10.39	M4	none

Table 9-4
Handset 3G mode variation on RF Emissions

IV. HAC Measurement Conditions for WCDMA

HAC is measured using the 12.2 kbps RMC with TPC bits configured to all "1s". HAC in AMR configurations is not required when the maximum average output of each RF channel for 12.2 kbps AMR is less than ¼ dB higher than that measured in 12.2 kbps RMC. Otherwise, HAC is measured on the maximum output channel in 12.2 AMR with a 3.4 kbps SRB (signaling radio bearer) using the configuration that results in the highest HAC for that RF channel in 12.2 RMC.

10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSCHI605
Model:	SCH-I605
S/N:	332F0

I. E-FIELD EMISSIONS:

Table 10-1
CDMA HAC Data Summary for E-field, RC1/SO3

Band	Channel	Backlight	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions												
CDMA	1013	off	SO3/RC1	Acoustic	24.88	11.88	35.9	31.1	51.0	-19.89	M4	none
CDMA	384	off	SO3/RC1	Acoustic	24.77	11.13	33.7	30.5	51.0	-20.46	M4	none
CDMA	777	off	SO3/RC1	Acoustic	24.76	14.35	43.4	32.8	51.0	-18.25	M4	none
PCS	25	off	SO3/RC1	Acoustic	24.16	12.70	40.0	32.0	41.0	-8.96	M4	none
PCS	600	off	SO3/RC1	Acoustic	24.42	10.23	32.2	30.2	41.0	-10.83	M4	none
PCS	1175	off	SO3/RC1	Acoustic	24.58	10.38	32.7	30.3	41.0	-10.71	M4	none

Table 10-2
CDMA HAC Data Summary for E-field, RC1/SO55

Band	Channel	Backlight	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions												
CDMA	1013	off	SO55/RC1	Acoustic	24.94	32.51	30.2	29.6	51.0	-21.41	M4	none
CDMA	384	off	SO55/RC1	Acoustic	24.82	29.64	27.5	28.8	51.0	-22.21	M4	none
CDMA	777	off	SO55/RC1	Acoustic	24.76	41.73	38.7	31.8	51.0	-19.24	M4	none
PCS	25	off	SO55/RC1	Acoustic	24.38	37.80	37.4	31.5	41.0	-9.54	M4	none
PCS	600	off	SO55/RC1	Acoustic	24.36	29.06	28.8	29.2	41.0	-11.82	M4	none
PCS	1175	off	SO55/RC1	Acoustic	24.41	29.79	29.5	29.4	41.0	-11.61	M4	none

Table 10-3
GSM HAC Data Summary for E-field

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions											
GSM850	128	off	Acoustic	32.77	33.75	95.5	39.60	48.50	-8.90	M4	none
GSM850	190	off	Acoustic	32.67	28.81	81.5	38.22	48.50	-10.28	M4	none
GSM850	251	off	Acoustic	32.36	35.18	99.5	39.96	48.50	-8.54	M4	none
GSM1900	512	off	Acoustic	29.40	21.03	58.7	35.37	38.50	-3.13	M3	none
GSM1900	661	off	Acoustic	29.65	21.88	61.0	35.71	38.50	-2.79	M3	none
GSM1900	810	off	Acoustic	29.55	20.64	57.6	35.21	38.50	-3.29	M3	none

Table 10-4
WCDMA HAC Data Summary for E-field

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions											
WCDMA850	4132	off	Acoustic	22.45	67.62	65.0	36.3	51.0	-14.74	M4	none
WCDMA850	4183	off	Acoustic	22.29	59.48	57.2	35.1	51.0	-15.86	M4	none
WCDMA850	4233	off	Acoustic	22.40	57.06	54.8	34.8	51.0	-16.22	M4	none
WCDMA1900	9262	off	Acoustic	22.48	41.41	40.3	32.1	41.0	-8.90	M4	none
WCDMA1900	9400	off	Acoustic	22.35	43.36	42.2	32.5	41.0	-8.50	M4	none
WCDMA1900	9538	off	Acoustic	22.49	33.20	32.3	30.2	41.0	-10.82	M4	none

II. H-FIELD EMISSIONS:

Table 10-5
CDMA HAC Data Summary for H-field, RC1/SO3

Mode	Channel	Backlight	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions												
CDMA	1013	off	SO3/RC1	Acoustic	24.88	0.0285	0.083	-21.7	0.6	-22.26	M4	none
CDMA	384	off	SO3/RC1	Acoustic	24.77	0.0198	0.057	-24.8	0.6	-25.44	M4	none
CDMA	777	off	SO3/RC1	Acoustic	24.76	0.0265	0.077	-22.3	0.6	-22.91	M4	none
PCS	25	off	SO3/RC1	Acoustic	24.16	0.0274	0.078	-22.1	-9.4	-12.74	M4	none
PCS	600	off	SO3/RC1	Acoustic	24.42	0.0306	0.087	-21.2	-9.4	-11.78	M4	none
PCS	1175	off	SO3/RC1	Acoustic	24.58	0.0228	0.065	-23.8	-9.4	-14.35	M4	none

Table 10-6
CDMA HAC Data Summary for H-field, RC1/SO55

Mode	Channel	Backlight	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions												
CDMA	1013	off	SO55/RC1	Acoustic	24.94	0.0637	0.051	-25.8	0.6	-26.37	M4	none
CDMA	384	off	SO55/RC1	Acoustic	24.82	0.0526	0.042	-27.4	0.6	-28.04	M4	none
CDMA	777	off	SO55/RC1	Acoustic	24.76	0.0722	0.058	-24.7	0.6	-25.28	M4	none
PCS	25	off	SO55/RC1	Acoustic	24.38	0.0825	0.068	-23.4	-9.4	-14.00	M4	none
PCS	600	off	SO55/RC1	Acoustic	24.36	0.0648	0.053	-25.5	-9.4	-16.10	M4	none
PCS	1175	off	SO55/RC1	Acoustic	24.41	0.0655	0.054	-25.4	-9.4	-16.00	M4	none

Table 10-7
GSM HAC Data Summary for H-field

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions											
GSM850	128	off	Acoustic	32.77	0.0628	0.122	-18.3	-1.9	-16.35	M4	none
GSM850	190	off	Acoustic	32.67	0.0643	0.125	-18.0	-1.9	-16.14	M4	none
GSM850	251	off	Acoustic	32.36	0.0540	0.105	-19.6	-1.9	-17.66	M4	none
GSM1900	512	off	Acoustic	29.40	0.0387	0.090	-20.9	-11.9	-9.05	M4	none
GSM1900	661	off	Acoustic	29.65	0.0426	0.099	-20.1	-11.9	-8.20	M4	none
GSM1900	810	off	Acoustic	29.55	0.0531	0.123	-18.2	-11.9	-6.29	M4	none

Table 10-8
WCDMA HAC Data Summary for H-field

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions											
WCDMA850	4132	off	Acoustic	22.45	0.1107	0.102	-19.8	0.6	-20.40	M4	none
WCDMA850	4183	off	Acoustic	22.29	0.1260	0.116	-18.7	0.6	-19.28	M4	none
WCDMA850	4233	off	Acoustic	22.40	0.0965	0.089	-21.0	0.6	-21.60	M4	none
WCDMA1900	9262	off	Acoustic	22.48	0.0774	0.073	-22.8	-9.4	-13.37	M4	none
WCDMA1900	9400	off	Acoustic	22.35	0.0896	0.084	-21.5	-9.4	-12.09	M4	none
WCDMA1900	9538	off	Acoustic	22.49	0.0822	0.077	-22.2	-9.4	-12.84	M4	none

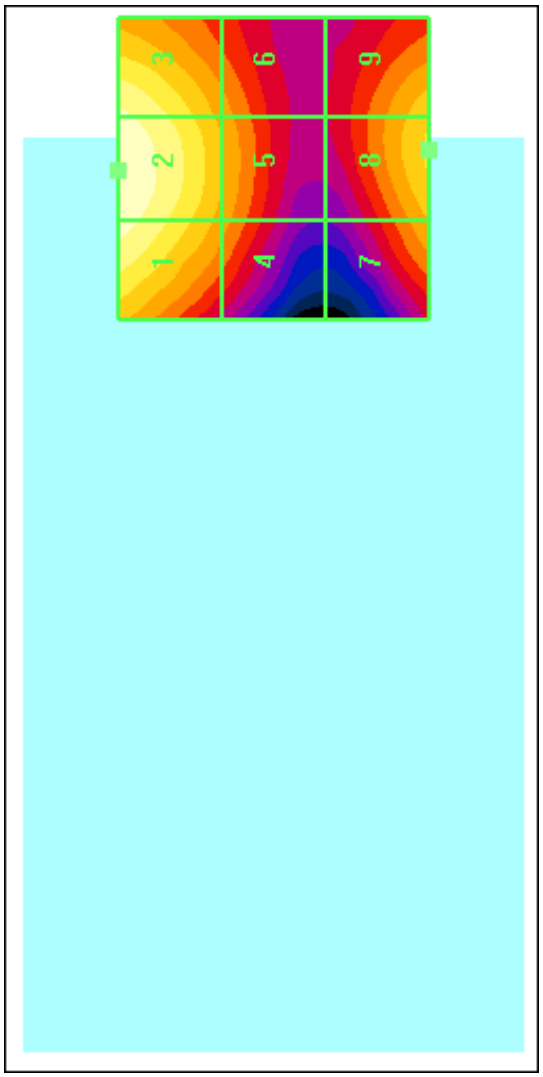


Figure 10-1
Sample E-field Scan Overlay

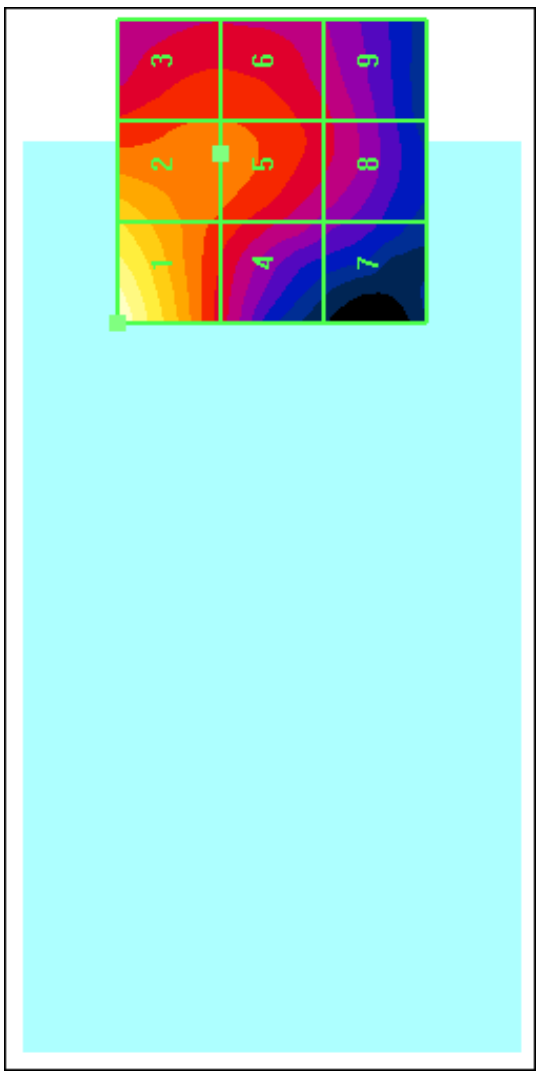


Figure 10-2
Sample H-field Scan Overlay

Note: See Test Setup Photographs for actual WD overlay

III. Worst-case Configuration Evaluation

Table 10-9
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Backlight	Scan Center	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT
Probe Rotation at Worst-Case									
GSM1900	661	off	Acoustic	22.10	61.6	35.80	**38.50**	**-2.70**	M3

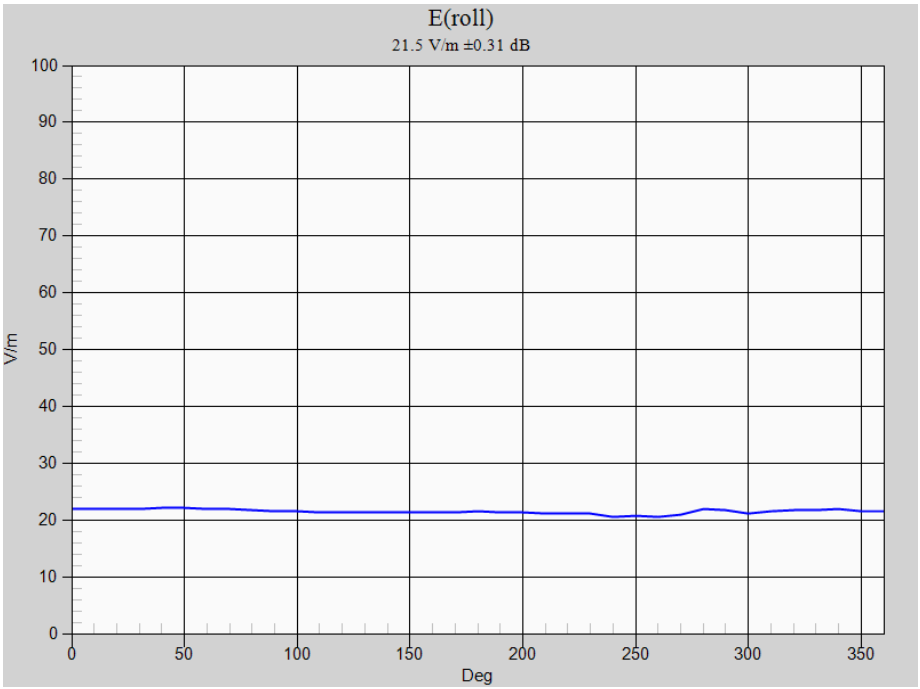


Figure 10-3
Worst-Case Probe Rotation about Azimuth axis

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 10-1 or Figure 10-2 denoted by the green square markers.

11. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4407B	ESA Spectrum Analyzer	4/3/2012	Annual	4/3/2013	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	3/15/2012	Annual	3/15/2013	US40053896
Agilent	E5515C	Wireless Communications Test Set	10/10/2011	Annual	10/10/2012	GB46110872
Agilent	E5515C	Wireless Communications Test Set	10/14/2011	Annual	10/14/2012	GB41450275
Agilent	E5515C	Wireless Communications Test Set	10/20/2011	Annual	10/20/2012	GB46310798
Agilent	E5515C	Wireless Communications Test Set	2/9/2012	Annual	2/9/2013	GB43460554
Agilent	E5515C	Wireless Communications Test Set	2/12/2012	Annual	2/12/2013	GB45360985
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43304447
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43163447
Anritsu	MA2481A	Power Sensor	2/14/2012	Annual	2/14/2013	3681
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014497
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014488
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMU200	Base Station Simulator	5/22/2012	Annual	5/22/2013	109892
Rohde & Schwarz	NRVD	Dual Channel Power Meter	4/8/2011	Biennial	4/8/2013	101695
Seekonk	NC-100	Torque Wrench (8" lb)	11/29/2011	Triennial	11/29/2014	21053
SPEAG	DAE3	Dasy Data Acquisition Electronics	11/9/2011	Annual	11/9/2012	455
SPEAG	DAE4	Dasy Data Acquisition Electronics	1/18/2012	Annual	1/18/2013	1272
SPEAG	DAE4	Dasy Data Acquisition Electronics	2/20/2012	Annual	2/20/2013	649
SPEAG	DAE4	Dasy Data Acquisition Electronics	4/19/2012	Annual	4/19/2013	665
SPEAG	DAE4	Dasy Data Acquisition Electronics	5/15/2012	Annual	5/15/2013	859
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/9/2011	Biennial	2/9/2013	1137
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/8/2011	Biennial	2/8/2013	1003
SPEAG	ER3DV6	Freespace E-field Probe	1/20/2012	Annual	1/20/2013	2353
SPEAG	H3DV6	Freespace H-field Probe	1/20/2012	Annual	1/20/2013	6207

Table 11-1
Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST)

*** Note: CBT (Calibrated Before Testing).** Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

12. MEASUREMENT UNCERTAINTY

Wireless Communications Device Near-Field Measurement Uncertainty Estimation								
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Ci (H)	Unc. (dB)	Notes/Comments
Measurement System								
RF System Reflections	0.50	Tolerance	N	1.00	1	1	0.50	Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	1	0.01	
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	1	0.16	
Boundary Effects	0.105	Accuracy	R	1.73	1	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.670	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.670	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	1	0.03	*
Resolution to 2mm error	0.210	Tolerance	N	1.00	1	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	1	0.17	
Test Sample Related								
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	1	0.12	
Combined Standard Uncertainty (k=1)							0.66	16.5%
Expanded Uncertainty [95% confidence] (k=2)							1.33	32.3%
Expanded Uncertainty [95% confidence] on Field							**0.66**	**16.2%**

Table 12-1
Uncertainty Estimation Table

Notes:
1. Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81 and NIST Tech Note 1297 and UKAS M3003.
2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

13. TEST DATA

See following Attached Pages for Test Data.

PCTEST Hearing-Aid Compatability Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

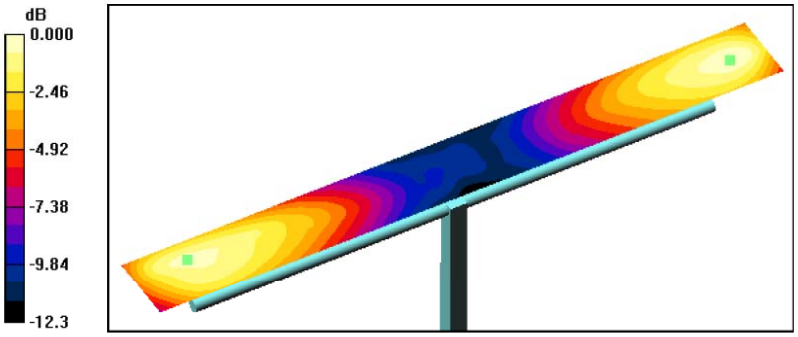
Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

835 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 101.6 V/m; Power Drift = 0.174 dB
Average value of Peak (interpolated) = 162.4 V/m



0 dB = 166.8V/m

Date: 8/30/2012

PCTEST Hearing-Aid Compatability Facility

DUT: CD835V3 - SN1003

Type: CD835V3
Serial: 1003

Communication System: CW; Frequency: 835 MHz;

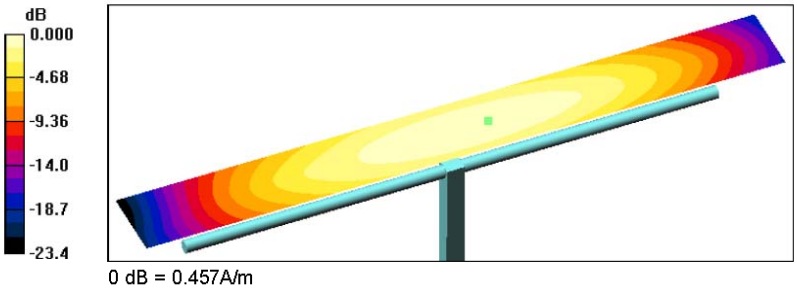
Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

835 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.473 A/m; Power Drift = -0.032 dB
Maximum value of Total (interpolated) = 0.457 A/m



0 dB = 0.457A/m

Date: 8/30/2012

PCTEST Hearing-Aid Compatability Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

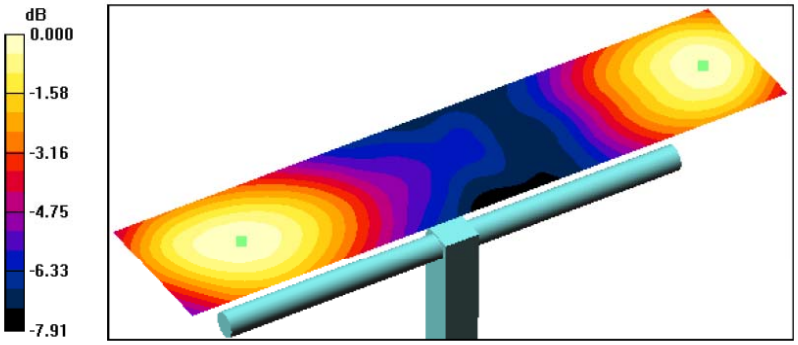
Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1880 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 160.7 V/m; Power Drift = 0.051 dB
Average value of Peak (interpolated) = 141.5 V/m



0 dB = 142.1V/m

Date: 8/30/2012

PCTEST Hearing-Aid Compatability Facility

DUT: CD1880V3 - SN1137

Type: CD1880V3
Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

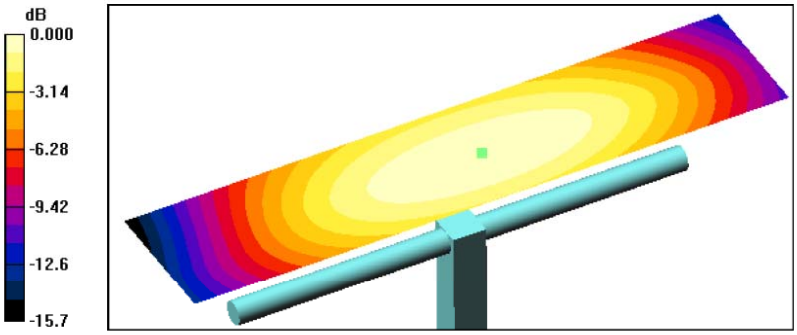
Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

1880 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.476 A/m; Power Drift = 0.184 dB
Maximum value of Total (interpolated) = 0.465 A/m



0 dB = 0.464A/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8

Communication System: CDMA; Frequency: 848.31 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, RC1/SO3, High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 43.4 V/m
Probe Modulation Factor = 3.025
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 17.3 V/m; Power Drift = -0.005 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **38.0 M4**	Grid 2 **39.6 M4**	Grid 3 **36.9 M4**
Grid 4 **40.0 M4**	Grid 5 **41.6 M4**	Grid 6 **38.3 M4**
Grid 7 **42.0 M4**	Grid 8 **43.4 M4**	Grid 9 **38.2 M4**

0 dB = 43.4V/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8

Communication System: CDMA; Frequency: 824.7 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, RC1/SO3, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.083 A/m
Probe Modulation Factor = 2.895
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.013 A/m; Power Drift = 0.195 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.083 M4**	Grid 2 **0.045 M4**	Grid 3 **0.055 M4**
Grid 4 **0.057 M4**	Grid 5 **0.044 M4**	Grid 6 **0.034 M4**
Grid 7 **0.057 M4**	Grid 8 **0.046 M4**	Grid 9 **0.035 M4**

0 dB = 0.083A/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8

Communication System: CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

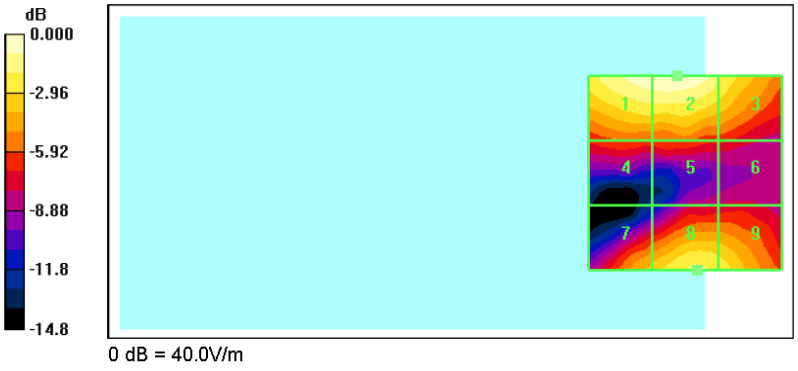
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, RC1/SO3, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 40.0 V/m
Probe Modulation Factor = 3.151
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 4.83 V/m; Power Drift = -0.198 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **38.7 M4**	Grid 2 **40.0 M4**	Grid 3 **32.7 M4**
Grid 4 **20.5 M4**	Grid 5 **21.2 M4**	Grid 6 **18.9 M4**
Grid 7 **26.7 M4**	Grid 8 **32.5 M4**	Grid 9 **31.0 M4**



0 dB = 40.0V/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8

Communication System: CDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, RC1/SO3, Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.087 A/m
Probe Modulation Factor = 2.853
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.028 A/m; Power Drift = 0.196 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.057 M4**	Grid 2 **0.063 M4**	Grid 3 **0.063 M4**
Grid 4 **0.057 M4**	Grid 5 **0.066 M4**	Grid 6 **0.067 M4**
Grid 7 **0.055 M4**	Grid 8 **0.087 M4**	Grid 9 **0.063 M4**

0 dB = 0.087A/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 848.31 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, RC1/SO55, High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 38.7 V/m
Probe Modulation Factor = 0.928
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 49.0 V/m; Power Drift = -0.032 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **32.7 M4**	Grid 2 **33.8 M4**	Grid 3 **31.1 M4**
Grid 4 **35.4 M4**	Grid 5 **36.0 M4**	Grid 6 **33.3 M4**
Grid 7 **38.2 M4**	Grid 8 **38.7 M4**	Grid 9 **34.1 M4**

0 dB = 38.7V/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 848.31 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

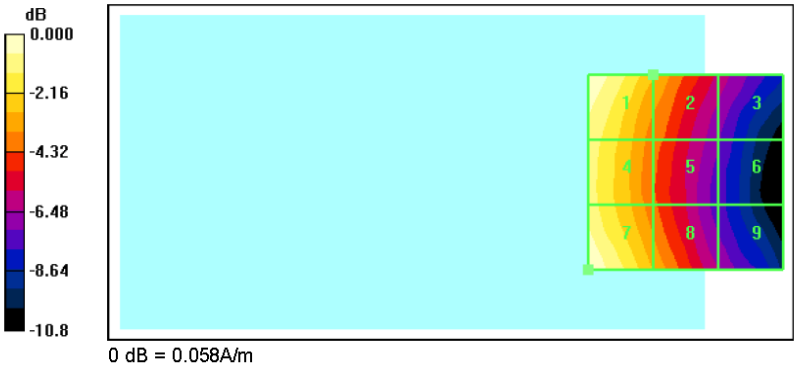
- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

Cell. CDMA, RC1/SO55, High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.058 A/m
Probe Modulation Factor = 0.808
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.037 A/m; Power Drift = -0.177 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.058 M4**	Grid 2 **0.042 M4**	Grid 3 **0.029 M4**
Grid 4 **0.052 M4**	Grid 5 **0.037 M4**	Grid 6 **0.026 M4**
Grid 7 **0.058 M4**	Grid 8 **0.042 M4**	Grid 9 **0.028 M4**



0 dB = 0.058A/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

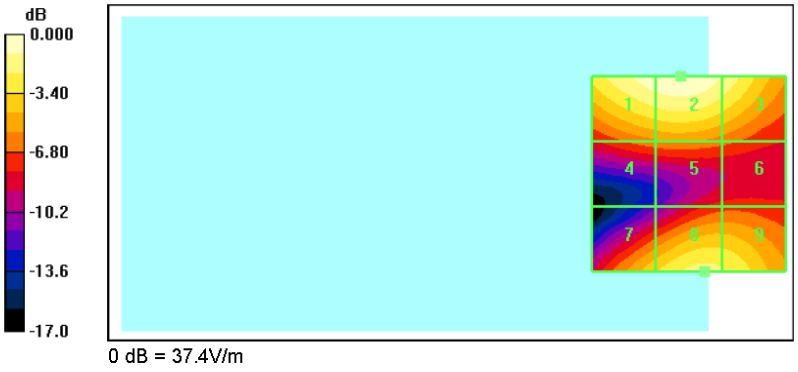
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, RC1/SO55, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 37.4 V/m
Probe Modulation Factor = 0.990
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 13.1 V/m; Power Drift = 0.194 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **36.0 M4**	Grid 2 **37.4 M4**	Grid 3 **32.7 M4**
Grid 4 **19.1 M4**	Grid 5 **19.8 M4**	Grid 6 **18.2 M4**
Grid 7 **25.1 M4**	Grid 8 **30.3 M4**	Grid 9 **29.3 M4**



0 dB = 37.4V/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: CDMA; Frequency: 1851.25 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

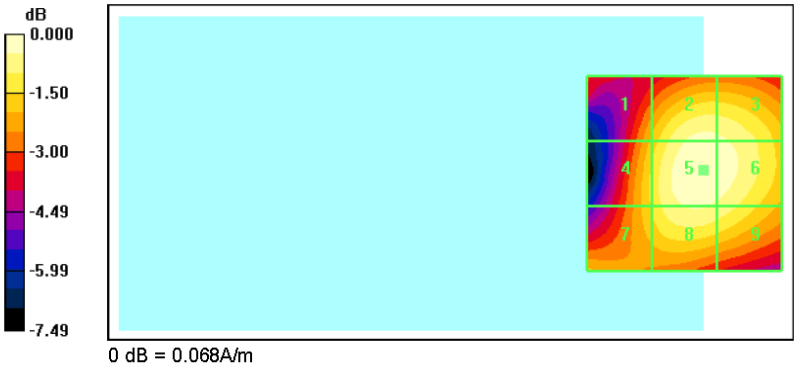
- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS CDMA, RC1/SO55, Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.068 A/m
Probe Modulation Factor = 0.820
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.100 A/m; Power Drift = 0.128 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.055 M4**	Grid 2 **0.066 M4**	Grid 3 **0.065 M4**
Grid 4 **0.058 M4**	Grid 5 **0.068 M4**	Grid 6 **0.067 M4**
Grid 7 **0.058 M4**	Grid 8 **0.065 M4**	Grid 9 **0.063 M4**



0 dB = 0.068A/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM850 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 99.5 V/m
Probe Modulation Factor = 2.829
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 42.0 V/m; Power Drift = 0.178 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **81.0 M4**	Grid 2 **87.4 M4**	Grid 3 **82.8 M4**
Grid 4 **86.0 M4**	Grid 5 **93.4 M4**	Grid 6 **88.9 M4**
Grid 7 **91.4 M4**	Grid 8 **99.5 M4**	Grid 9 **92.9 M4**

0 dB = 99.5V/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 836.6 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

GSM850 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.125 A/m
Probe Modulation Factor = 1.948
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.035 A/m; Power Drift = -0.084 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.125 M4**	Grid 2 **0.091 M4**	Grid 3 **0.062 M4**
Grid 4 **0.110 M4**	Grid 5 **0.081 M4**	Grid 6 **0.053 M4**
Grid 7 **0.114 M4**	Grid 8 **0.082 M4**	Grid 9 **0.051 M4**

0 dB = 0.125A/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

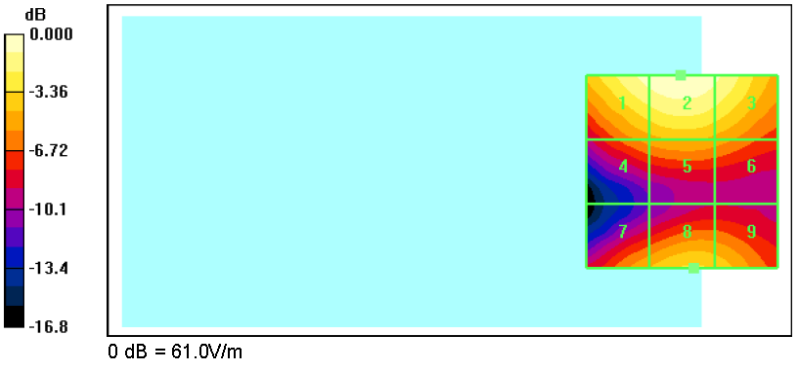
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS GSM Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 61.0 V/m
Probe Modulation Factor = 2.79
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 10.2 V/m; Power Drift = 0.192 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1 **57.1 M3**	Grid 2 **61.0 M3**	Grid 3 **55.6 M3**
Grid 4 **34.4 M4**	Grid 5 **37.2 M4**	Grid 6 **35.0 M4**
Grid 7 **36.6 M4**	Grid 8 **42.5 M4**	Grid 9 **40.7 M4**



0 dB = 61.0V/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

PCS GSM High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.123 A/m
Probe Modulation Factor = 2.319
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.045 A/m; Power Drift = 0.080 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1 **0.123 M4**	Grid 2 **0.104 M4**	Grid 3 **0.088 M4**
Grid 4 **0.086 M4**	Grid 5 **0.090 M4**	Grid 6 **0.088 M4**
Grid 7 **0.072 M4**	Grid 8 **0.080 M4**	Grid 9 **0.080 M4**

0 dB = 0.123A/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 826.4 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

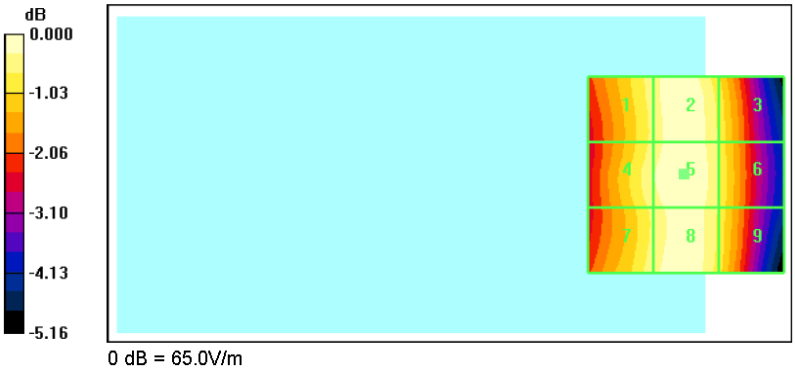
- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 65.0 V/m
Probe Modulation Factor = 0.961
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 90.0 V/m; Power Drift = -0.195 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **61.4 M4**	Grid 2 **64.2 M4**	Grid 3 **59.6 M4**
Grid 4 **62.2 M4**	Grid 5 **65.0 M4**	Grid 6 **60.1 M4**
Grid 7 **61.6 M4**	Grid 8 **64.3 M4**	Grid 9 **59.6 M4**



0 dB = 65.0V/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 836.6 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA850 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.116 A/m
Probe Modulation Factor = 0.924
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.065 A/m; Power Drift = -0.140 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.116 M4**	Grid 2 **0.086 M4**	Grid 3 **0.057 M4**
Grid 4 **0.103 M4**	Grid 5 **0.076 M4**	Grid 6 **0.048 M4**
Grid 7 **0.106 M4**	Grid 8 **0.075 M4**	Grid 9 **0.045 M4**

0 dB = 0.116A/m

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: ER3DV6 - SN2353; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 42.1 V/m
Probe Modulation Factor = 0.972
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 24.0 V/m; Power Drift = -0.106 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **39.3 M4**	Grid 2 **42.1 M4**	Grid 3 **38.5 M4**
Grid 4 **24.2 M4**	Grid 5 **26.6 M4**	Grid 6 **25.4 M4**
Grid 7 **27.2 M4**	Grid 8 **29.9 M4**	Grid 9 **28.0 M4**

0 dB = 42.1V/m

Date: 9/4/2012

PCTEST Hearing-Aid Compatability Facility

DUT: A3LSCHI605

Type: Portable Handset
Serial: 332F0
Backlight off
Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1880 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

DASY5 Configuration:

- Probe: H3DV6 - SN6207; Calibrated: 1/20/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

WCDMA1900 Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.084 A/m
Probe Modulation Factor = 0.940
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.106 A/m; Power Drift = 0.122 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.078 M4**	Grid 2 **0.084 M4**	Grid 3 **0.081 M4**
Grid 4 **0.074 M4**	Grid 5 **0.084 M4**	Grid 6 **0.082 M4**
Grid 7 **0.068 M4**	Grid 8 **0.077 M4**	Grid 9 **0.075 M4**

0 dB = 0.084A/m

14. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

Certificate No: ER3-2353_Jan12

CALIBRATION CERTIFICATE

Object	ER3DV6 - SN:2353
Calibration procedure(s)	QA CAL-02.v6, QA CAL-25.v4 Calibration procedure for E-field probes optimized for close near field evaluations in air
Calibration date:	January 20, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

✓ KOK 2/6/2012

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe ER3DV6	SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12
DAE4	SN: 789	6-Apr-11 (No. DAE4-789_Apr11)	Apr-12
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

	Name	Function	Signature
Calibrated by:	Dimce Iliev	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: January 25, 2012

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *NORM(f)x,y,z = NORMx,y,z * frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *PAR:* PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- *Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. *VR* is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORMx* (no uncertainty required).

Probe ER3DV6

SN:2353

Manufactured: March 8, 2005
Calibrated: January 20, 2012

Calibrated for DASY/EASY Systems
(Note: non-compatible with DASY2 system!)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.53	1.73	1.81	± 10.1 %
DCP (mV)[B]	100.9	98.7	102.3	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc[E] (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	103.6	±3.0 %
			Y	0.00	0.00	1.00	88.2	
			Z	0.00	0.00	1.00	105.7	
10011	UMTS-FDD (WCDMA)	3.40	X	3.44	65.6	18.3	111.4	±0.7 %
			Y	3.51	65.9	18.5	130.9	
			Z	3.53	66.6	18.9	114.5	
10021	GSM-FDD (TDMA, GMSK)	9.40	X	16.75	99.3	28.2	144.6	±1.7 %
			Y	16.85	99.3	28.8	124.1	
			Z	22.94	99.8	28.7	128.7	
10039	CDMA2000 (1xRTT, RC1)	4.57	X	4.56	66.0	18.8	112.4	±0.9 %
			Y	4.84	67.1	19.5	133.1	
			Z	4.49	65.9	18.7	115.8	
10081	CDMA2000 (1xRTT, RC3)	3.96	X	3.68	64.9	18.0	109.1	±0.7 %
			Y	3.89	65.9	18.7	129.0	
			Z	3.71	65.4	18.4	113.2	
10169	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, QPSK)	5.73	X	5.16	67.7	20.5	145.7	±1.7 %
			Y	5.14	67.1	20.3	124.7	
			Z	4.82	65.7	19.3	108.5	
10170	LTE-FDD (SC-FDMA, 1 RB, 20 MHz, 16-QAM)	6.52	X	6.10	69.5	21.9	146.2	±2.7 %
			Y	6.13	69.1	21.8	125.5	
			Z	5.66	67.0	20.2	110.4	
10175	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, QPSK)	5.73	X	5.13	67.6	20.5	145.7	±1.7 %
			Y	5.15	67.1	20.3	124.9	
			Z	4.88	66.0	19.4	110.1	
10176	LTE-FDD (SC-FDMA, 1 RB, 10 MHz, 16-QAM)	6.52	X	6.12	69.6	22.0	145.7	±3.0 %
			Y	6.12	69.2	21.9	124.6	
			Z	5.69	67.2	20.4	110.6	
10177	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, QPSK)	5.73	X	5.19	67.8	20.6	145.8	±1.7 %
			Y	5.17	67.3	20.4	124.7	
			Z	4.88	66.0	19.4	110.3	
10178	LTE-FDD (SC-FDMA, 1 RB, 5 MHz, 16-QAM)	6.52	X	6.05	69.3	21.8	146.8	±2.5 %
			Y	5.98	68.5	21.5	123.9	
			Z	5.55	66.6	20.1	109.9	
10181	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, QPSK)	5.73	X	5.17	67.8	20.6	145.9	±1.7 %
			Y	4.92	66.1	19.7	123.5	
			Z	4.90	66.1	19.5	110.0	

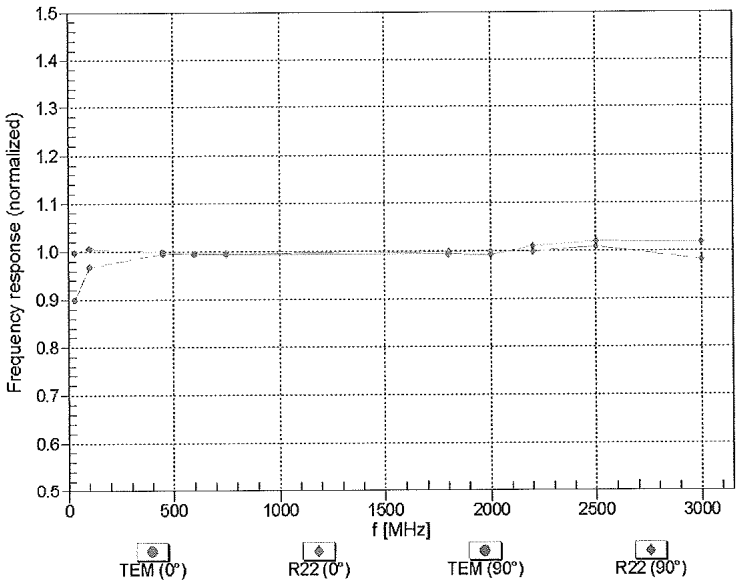
10182	LTE-FDD (SC-FDMA, 1 RB, 15 MHz, 16-QAM)	6.52	X	6.00	69.1	21.7	146.3	±3.0 %
			Y	6.43	70.5	22.6	125.7	
			Z	5.70	67.2	20.4	110.4	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[B] Numerical linearization parameter: uncertainty not required.
[E] Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

Frequency Response of E-Field

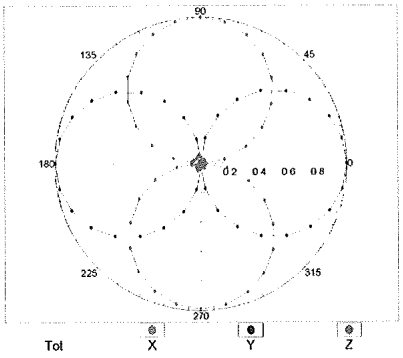
(TEM-Cell:ifi110 EXX, Waveguide: R22)



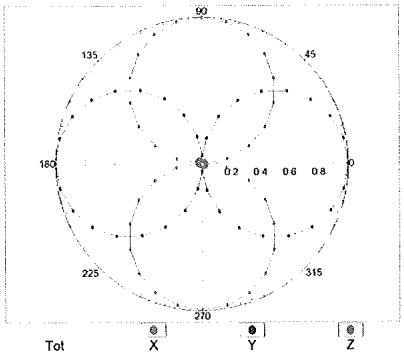
Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Receiving Pattern (ϕ), ϑ = 0°

f=600 MHz,TEM,0°

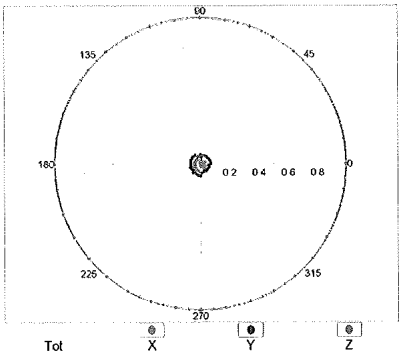


f=2500 MHz,R22,0°

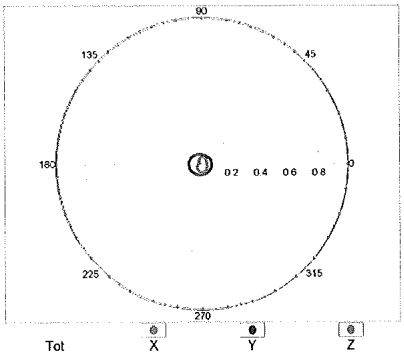


Receiving Pattern (ϕ), ϑ = 90°

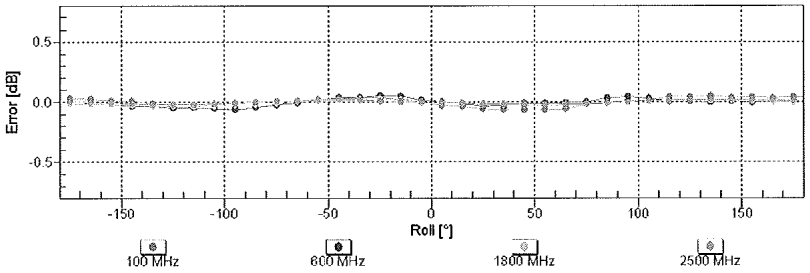
f=600 MHz,TEM,90°



f=2500 MHz,R22,90°

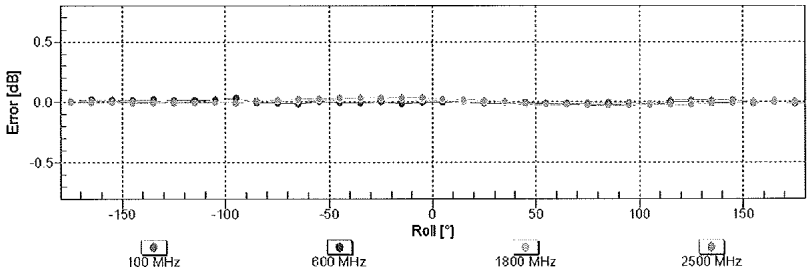


Receiving Pattern (ϕ), ϑ = 0°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

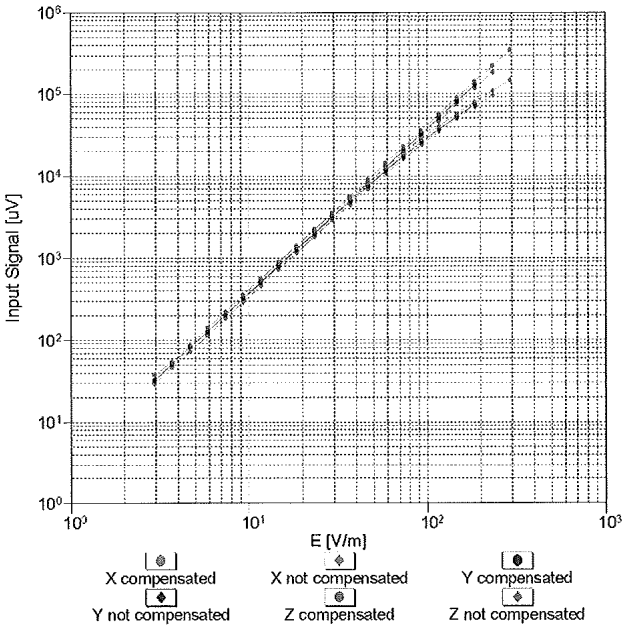
Receiving Pattern (ϕ), ϑ = 90°

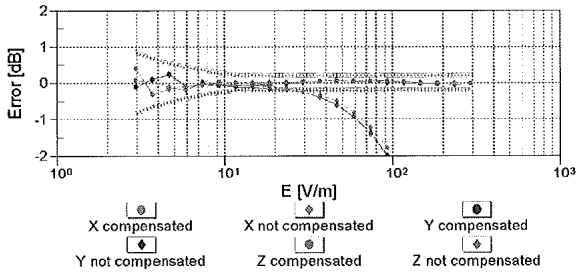


Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Dynamic Range f(E-field)

(TEM cell , f = 900 MHz)

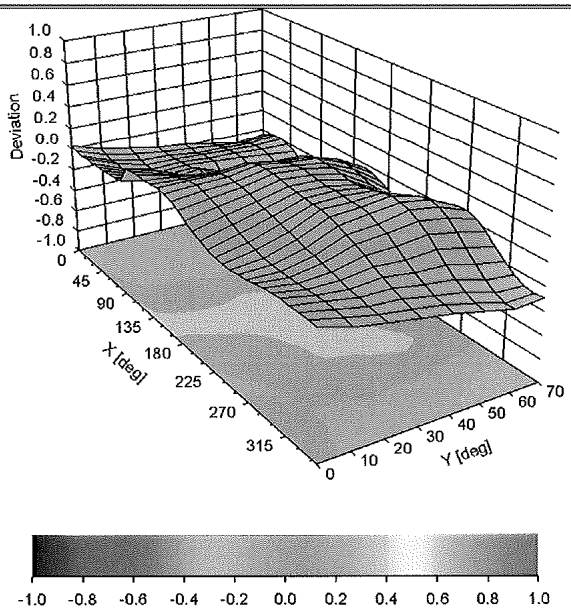




Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Deviation from Isotropy in Air

Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2353

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-4.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

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Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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Accreditation No.: SCS 108

Client PC Test

Certificate No: H3-6207_Jan12

CALIBRATION CERTIFICATE

Object: H3DV6 - SN:6207

Calibration procedure(s): QA CAL-03.v6, QA CAL-25.v4
Calibration procedure for H-field probes optimized for close near field evaluations in air

Calibration date: January 20, 2012

✓ ok 2/6/12

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	31-Mar-11 (No. 217-01372)	Apr-12
Power sensor E4412A	MY41498087	31-Mar-11 (No. 217-01372)	Apr-12
Reference 3 dB Attenuator	SN: S5054 (3c)	29-Mar-11 (No. 217-01369)	Apr-12
Reference 20 dB Attenuator	SN: S5086 (20b)	29-Mar-11 (No. 217-01367)	Apr-12
Reference 30 dB Attenuator	SN: S5129 (30b)	29-Mar-11 (No. 217-01370)	Apr-12
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	6-Apr-11 (No. DAE4-789_Apr11)	Apr-12
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

	Name	Function	Signature
Calibrated by:	Dimce Iliev	Laboratory Technician	D. Iliev
Approved by:	Katja Pokovic	Technical Manager	

Issued: January 25, 2012

Glossary:

NORMx,y,z	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., ϑ = 0 is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, " IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORMx,y,z:* Assessed for E-field polarization ϑ = 0 for XY sensors and ϑ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- *X,Y,Z(f)_a0a1a2= X,Y,Z_a0a1a2* frequency_response* (see Frequency Response Chart).
- *DCPx,y,z:* DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *PAR:* PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- *Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z*: *A, B, C* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. *VR* is the maximum calibration range expressed in RMS voltage across the diode.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *X_a0a1a2* (no uncertainty required).

Probe H3DV6

SN:6207

Manufactured: June 12, 2006
Calibrated: January 20, 2012

Calibrated for DASY/EASY Systems
(Note: non-compatible with DASY2 system!)

DASY/EASY - Parameters of Probe: H3DV6 - SN:6207

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / √(mV))	a0	2.41E-003	2.37E-003	2.94E-003	± 5.1 %
Norm (A/m / √(mV))	a1	1.77E-004	6.07E-004	8.69E-005	± 5.1 %
Norm (A/m / √(mV))	a2	1.63E-004	2.45E-004	1.96E-004	± 5.1 %
DCP (mV)[B]		94.0	94.6	94.5	

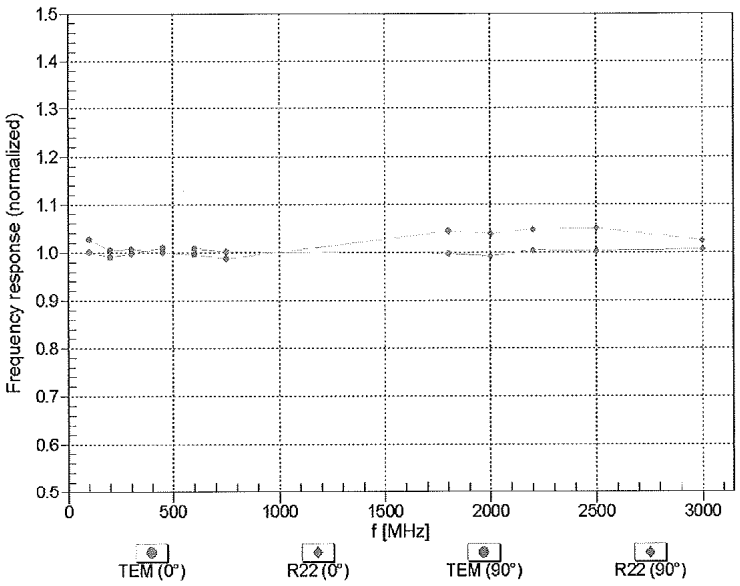
Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc[E] (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	92.5	±2.7 %
			Y	0.00	0.00	1.00	107.4	
			Z	0.00	0.00	1.00	119.1	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

[B] Numerical linearization parameter: uncertainty not required.
[E] Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

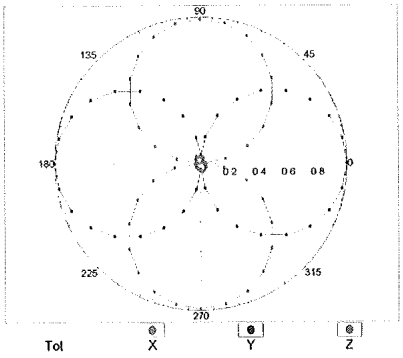
Frequency Response of H-Field
(TEM-Cell:ifi110 EXX, Waveguide: R22)



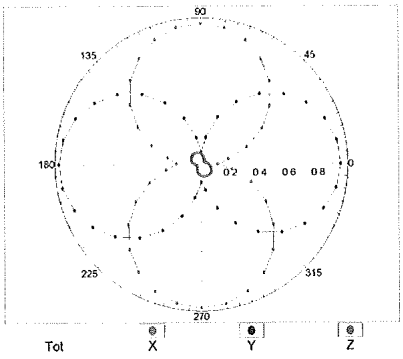
Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

Receiving Pattern (ϕ), ϑ = 0°

f=600 MHz,TEM,0°

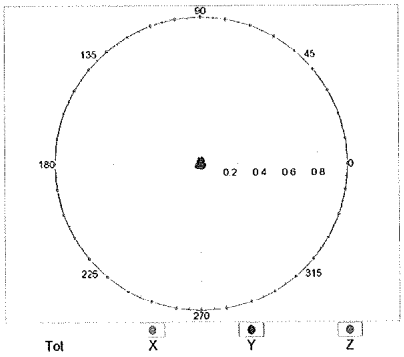


f=2500 MHz,R22,0°

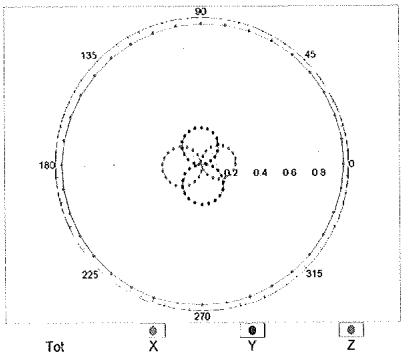


Receiving Pattern (ϕ), ϑ = 90°

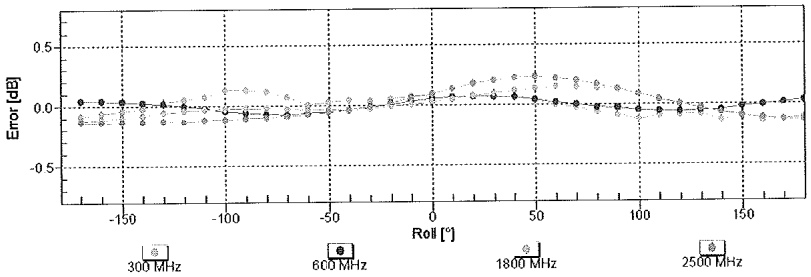
f=600 MHz,TEM,90°



f=2500 MHz,R22,90°

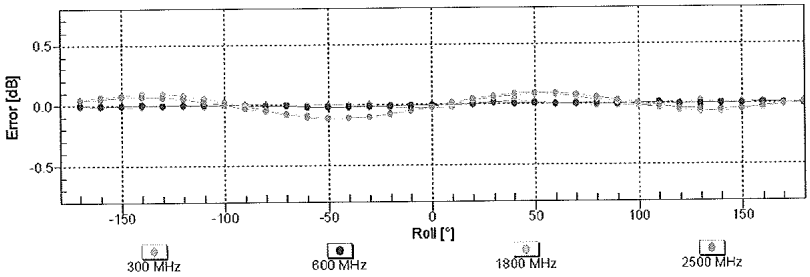


Receiving Pattern (ϕ), ϑ = 0°



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

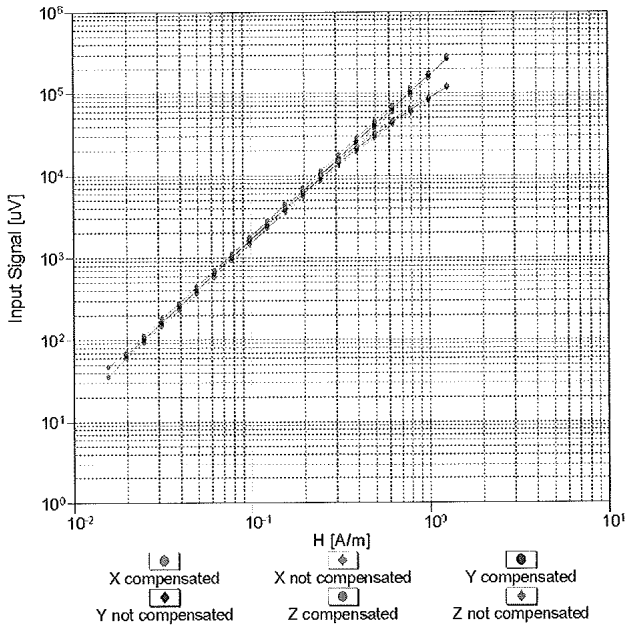
Receiving Pattern (ϕ), ϑ = 90°

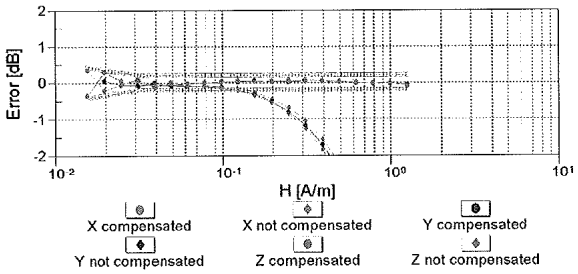


Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Dynamic Range f(H-field)

(TEM cell, f = 900 MHz)

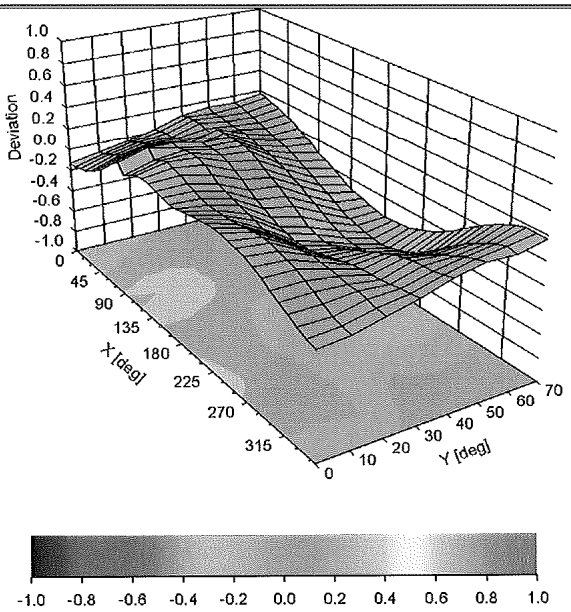




Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Deviation from Isotropy in Air

Error (ϕ, ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

DASY/EASY - Parameters of Probe: H3DV6 - SN:6207

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	179.8
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

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Accreditation No.: SCS 108

Client PC Test

Certificate No: CD835V3-1003_Feb11

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1003
Calibration procedure(s)	QA CAL-20.v5 Calibration procedure for dipoles in air
Calibration date:	February 08, 2011

K01C 2/22/11

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: February 10, 2011

References

[1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
  It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E- field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	**835 MHz** ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW forward power	**0.458 A/m**

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end-	100 mW forward power	170.7 V/m
Maximum measured above low end	100 mW forward power	161.3 V/m
Averaged maximum above arm	100 mW forward power	**166.0 V/m**

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	**Return Loss**	**Impedance**
800 MHz	16.6 dB	(41.9 – j11.1) Ohm
835 MHz	**24.1 dB**	**(48.2 + j5.9) Ohm**
900 MHz	16.5 dB	(58.5 – j14.0) Ohm
950 MHz	17.9 dB	(49.3 + j12.8) Ohm
960 MHz	12.9 dB	(62.2 + j22.8) Ohm

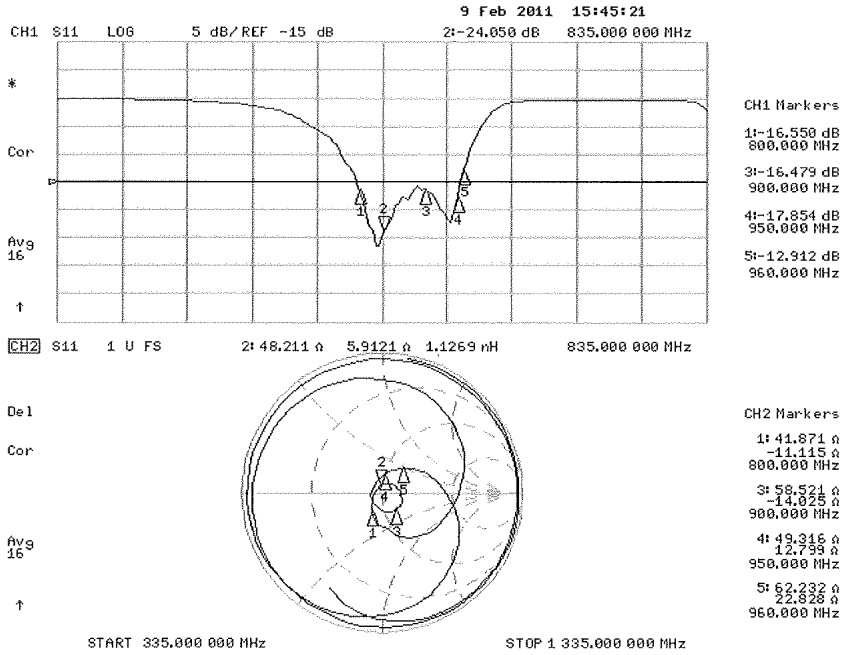
3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.3 DASY4 H-field Result

Date/Time: 08.02.2011 13:00:11

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_H_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

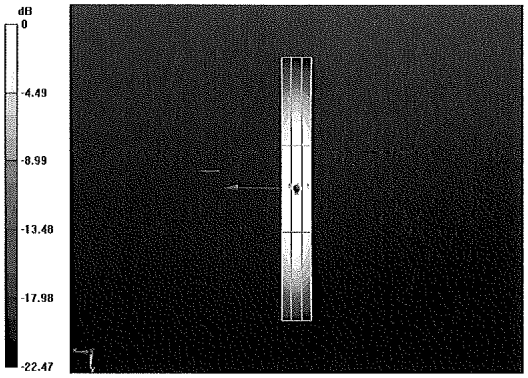
DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.458 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.488 A/m; Power Drift = -0.0088 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.376 M4**	Grid 2 **0.398 M4**	Grid 3 **0.379 M4**
Grid 4 **0.435 M4**	Grid 5 **0.458 M4**	Grid 6 **0.434 M4**
Grid 7 **0.388 M4**	Grid 8 **0.407 M4**	Grid 9 **0.381 M4**



0 dB = 0.460A/m

3.3.2 DASY4 E-field Result

Date/Time: 08.02.2011 13:58:56

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1003_E_110208_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

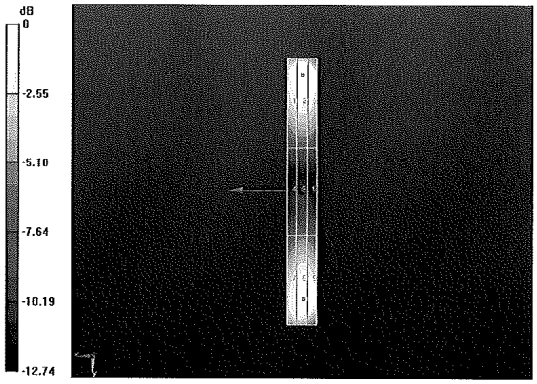
DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 170.7 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 123.4 V/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **164.3 M4**	Grid 2 **170.7 M4**	Grid 3 **164.5 M4**
Grid 4 **85.8 M4**	Grid 5 **90.5 M4**	Grid 6 **88.8 M4**
Grid 7 **152.9 M4**	Grid 8 **161.3 M4**	Grid 9 **158.3 M4**



0 dB = 170.7V/m

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland

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S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

Certificate No: CD1880V3-1137_Feb11/2

CALIBRATION CERTIFICATE (Replacement of No: CD1880V3-1137_Feb11)

Object	CD1880V3 - SN: 1137
Calibration procedure(s)	QA CAL-20.v5 Calibration procedure for dipoles in air
Calibration date:	February 09, 2011

V Kok 2/24/11

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-10 (No. 217-01266)	Oct-11
Power sensor HP 8481A	US37292783	06-Oct-10 (No. 217-01266)	Oct-11
Probe ER3DV6	SN: 2336	29-Dec-10 (No. ER3-2336_Dec10)	Dec-11
Probe H3DV6	SN: 6065	29-Dec-10 (No. H3-6065_Dec10)	Dec-11
DAE4	SN: 781	20-Oct-10 (No. DAE4-781_Oct10)	Oct-11

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-10)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-10)	In house check: Oct-11
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	
Approved by:	Katja Pokovic	Technical Manager	

Issued: February 23, 2011

References

[1] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- *Coordinate System:* y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- *Measurement Conditions:* Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- *Antenna Positioning:* The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections.
  It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- *Feed Point Impedance and Return Loss:* These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- *E- field distribution:* E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- *H-field distribution:* H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

1. Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	**1880 MHz** ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2. Maximum Field values

H-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured	100 mW forward power	**0.460 A/m**

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW forward power	139.0 V/m
Maximum measured above low end	100 mW forward power	134.5 V/m
Averaged maximum above arm	100 mW forward power	**136.8 V/m**

Uncertainty for E-field measurement: 12.8% (k=2)

3. Appendix

3.1 Antenna Parameters

Frequency	**Return Loss**	**Impedance**
1730 MHz	23.0 dB	(49.6 + j7.1) Ohm
1880 MHz	**21.2 dB**	**(51.1 + j8.7) Ohm**
1900 MHz	21.8 dB	(53.3 + j7.7) Ohm
1950 MHz	28.1 dB	(54.1 – j0.2) Ohm
2000 MHz	20.5 dB	(41.4 – j0.8) Ohm

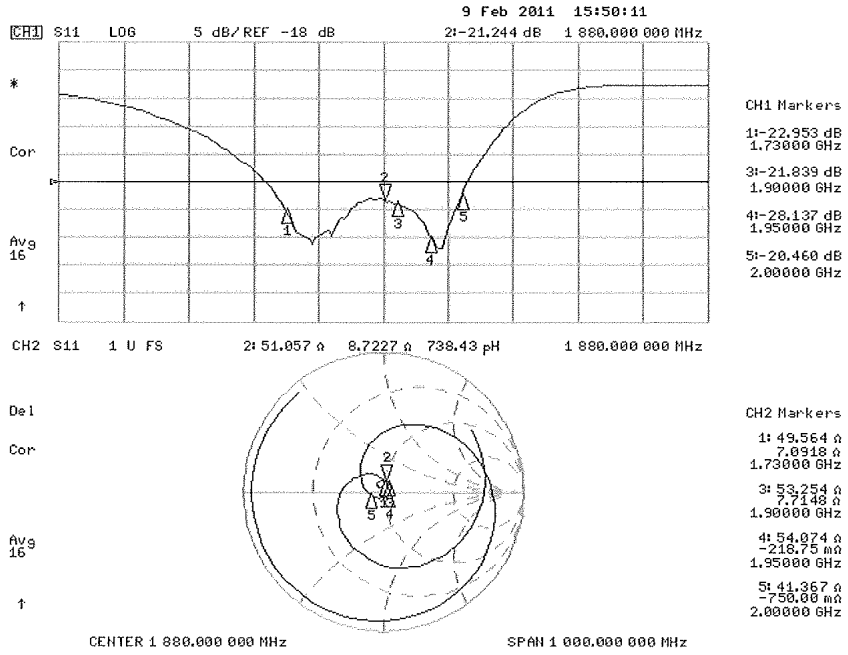
3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-Field Result

Date/Time: 09.02.2011 11:34:28

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

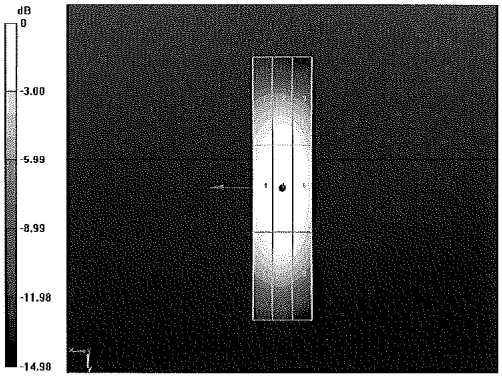
DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.460 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.487 A/m; Power Drift = 0.0057 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.401 M2**	Grid 2 **0.418 M2**	Grid 3 **0.396 M2**
Grid 4 **0.443 M2**	Grid 5 **0.460 M2**	Grid 6 **0.435 M2**
Grid 7 **0.409 M2**	Grid 8 **0.426 M2**	Grid 9 **0.399 M2**



0 dB = 0.460A/m

3.3.3 DASY4 E-Field Result

Date/Time: 08.02.2011 16:54:42

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

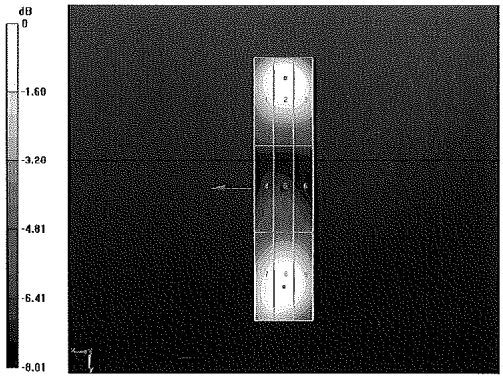
DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 139.0 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 138.8 V/m; Power Drift = -0.05 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **131.8** **M2**	Grid 2 **139.0** **M2**	Grid 3 **135.0** **M2**
Grid 4 **84.076** **M3**	Grid 5 **87.648** **M3**	Grid 6 **85.767** **M3**
Grid 7 **131.1** **M2**	Grid 8 **134.5** **M2**	Grid 9 **130.5** **M2**



0 dB = 139.0V/m

4. Additional Measurements

4.1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	**1730 MHz** ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

4.1.1 Maximum Field values

H-field 10 mm above dipole surface	condition	**interpolated maximum**
Maximum measured	100 mW forward power	**0.489 A/m**

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	**Interpolated maximum**
Maximum measured above high end	100 mW forward power	152.7 V/m
Maximum measured above low end	100 mW forward power	150.2 V/m
Averaged maximum above arm	100 mW forward power	**151.5 V/m**

Uncertainty for E-field measurement: 12.8% (k=2)

4.1.2 DASY4 H-field result

Date/Time: 09.02.2011 11:27:03

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_H_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

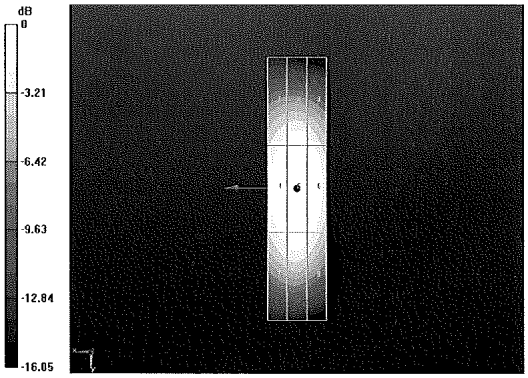
DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.489 A/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 0.519 A/m; Power Drift = 0.02 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 **0.407 M2**	Grid 2 **0.424 M2**	Grid 3 **0.403 M2**
Grid 4 **0.467 M2**	Grid 5 **0.489 M2**	Grid 6 **0.462 M2**
Grid 7 **0.418 M2**	Grid 8 **0.437 M2**	Grid 9 **0.409 M2**



0 dB = 0.490A/m

4.1.3 DASY4 E-field result

Date/Time: 08.02.2011 16:26:13

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1137_E_1730_110208_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz
Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m^3
Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

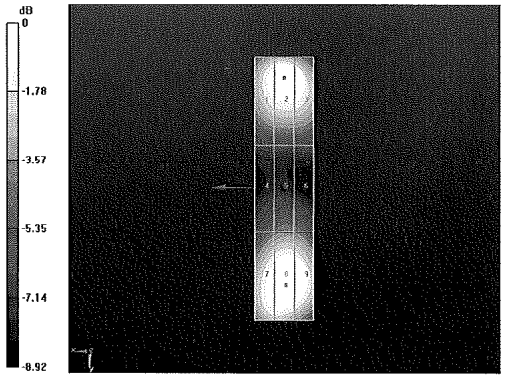
DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):
Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 152.7 V/m
Probe Modulation Factor = 1.000
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 156.8 V/m; Power Drift = 0.0092 dB
Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 **143.8 M2**	Grid 2 **150.2 M2**	Grid 3 **144.8 M2**
Grid 4 **97.621 M3**	Grid 5 **103.8 M3**	Grid 6 **102.2 M3**
Grid 7 **145.9 M2**	Grid 8 **152.7 M2**	Grid 9 **149.2 M2**



0 dB = 152.7V/m

15. CONCLUSION

The measurements taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 2.0, April 2010, indicate that the wireless communications device complies with the HAC limits specified in the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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